The Pennsylvania State University

The Graduate School

**College of Engineering** 

#### DESIGN, MODELING AND OPTIMIZATION OF PIEZOELECTRIC

#### ACTUATORS

A Dissertation in

Mechanical Engineering

by

Hareesh Kumar Reddy Kommepalli

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The dissertation of Hareesh Kumar Reddy Kommepalli was reviewed and approved<sup>\*</sup> by the following:

Christopher D. Rahn Professor of Mechanical Engineering Dissertation Co-Advisor Co-Chair of Committee

Srinivas A. Tadigadapa Associate Professor of Electrical Engineering Dissertation Co-Advisor Co-Chair of Committee

Ashok D. Belegundu Professor of Mechanical Engineering

M. Amanul Haque Associate Professor of Mechanical Engineering

Christopher L. Muhlstein Associate Professor of Materials Science and Engineering

Karen A. Thole Professor of Mechanical Engineering Department Head of Mechanical and Nuclear Engineering

\*Signatures are on file in the Graduate School.

## Abstract

Microactuators provide controlled motion and force for applications ranging from RF switches to microfluidic valves. Large amplitude response in piezoelectric actuators requires amplification of the small strain, exhibited by the piezoelectric material, used in the construction of such actuators. This research studies a uniflex microactuator that combines the strain amplification mechanisms of a unimorph and flexural motion to produce large displacement and blocking force. The design and fabrication of the proposed uniflex microactuator are described in detail. An analytical model is developed with three connected beams and a reflective symmetric boundary condition that predicts actuator displacement and blocking force as a function of the applied voltage. The model shows that the uniflex design requires appropriate parameter ranges, especially the clearance between the unimorph and aluminum cap, to ensure that both the unimorph and flexural amplification effects are realized. With a weakened joint at the unimorph/cap interface, the model is found to predict the displacement and blocking force of a uniflex actuators fabricated in this work. This research also compares the performance of a uniflex actuator in terms of its displacement and blocking force with uniflex and flextensional actuators. Analytical models for displacement and blocking force for all the three actuators are used in optimization, to study their relative performance. The uniflex actuator outperforms both unimorph and flextensional actuators in displacement, but, the unimorph actuator generates more blocking force. The uniflex actuator can therefore be used in applications that demand higher displacement and lower blocking force compared to a unimorph actuator.

This research introduces a novel T-beam actuator that can be fabricated by micromachining using a piezoelectric MEMS fabrication process or by dicing using a saw. With a T-shaped cross-section, and bottom and top flange and web electrodes, a cantilevered beam can bend in-plane and out-of-plane with unimorph actuation in both directions. Analytical models are developed to predict displacement, blocking force, and mechanical energy. Six prototypes of these T-beam actuators are fabricated by dicing and electrodes are deposited by photolithography and experimentally tested. The experimentally validated models are used to optimize the cross-section geometry for maximum displacement, blocking force, and mechanical energy. It is found that a cross section with ratio of web width b to total width s,  $b^*$ , and flange thickness t to total height h,  $t^*$ approaching zero produces maximum displacement. Also, the tip displacement is independent of bounding box of T-beam. The cross section with  $b^* = t^* = 0.381$  produces maximum blocking force, while,  $b^* = 0.25$ ,  $t^* = 0.33$  produces maximum mechanical energy. A properly designed T-beam has better free tip displacement per unit cross section area than a unimorph. Also, a flange actuated T-beam requires lower voltage than a unimorph to generate same electric field.

# **Table of Contents**

Figures	viii
Tables	xiv
wledgments	XV
er 1	
roduction	1
Applications	2
Macroactuators	3
Microactuators	5
Current Research	6
Organization of the Dissertation	7
er 2	
ign, Fabrication, and Performance of a Piezoelectric Uniflex Microac-	
tuator	8
Introduction	8
The Uniflex Actuator	9
Fabrication of the Uniflex Actuator	11
Uniflex Actuator Performance	14
2.4.1 Static Displacement Measurement	15
2.4.2 Blocking Force Measurement	18
Mathematical Modeling	20
Results and Discussion	26
2.6.1 Rigid Joint Model ( $K_t = \infty$ )	26
2.6.2 Weakened Joint Model ( $K_t < \infty$ )	29
	Figures   Tables   vledgments   r 1   oduction   Applications   Macroactuators   Microactuators   Current Research   Organization of the Dissertation   organization of the Dissertation   r 2   ign, Fabrication, and Performance of a Piezoelectric Uniflex Microactuator   Introduction   The Uniflex Actuator   Fabrication of the Uniflex Actuator   Vinflex Actuator Performance   2.4.1   Static Displacement Measurement   2.4.2   Blocking Force Measurement   2.4.2   Blocking Force Measurement   2.4.1   Static Displacement Measurement   2.4.2   Blocking Force Measurement   2.4.1   Static Displacement Measurement   2.4.2   Blocking Force Measurement   2.6.1 Rigid Joint Model ( $K_t = \infty$ )   2.6.2 Weakened Joint Model ( $K_t < \infty$ )

Chapte	r 3	
Ōpt	imization of Piezoelectric Uniflex Actuator	35
3.1	Introduction	35
3.2	Unimorph, Flextensional, and Uniflex Actuators	35
3.3	Mathematical Models	37
3.4	Optimal Design	40
	3.4.1 Maximized Displacement Design	42
	3.4.2 Maximized Blocking Force Design	45
Chapte	c 4	
Piez	oelectric T-beam Actuators	<b>48</b>
4.1	Introduction	48
4.2	The T-Beam Actuator Concept	50
4.3	Analytical Modeling	51
	4.3.1 Nondimensional modeling	57
4.4	Fabrication Process	59
4.5	Prototyping and Experimental Setup	61
4.6	Experimental Testing and Validation	64
4.7	Optimization of the T-beam Cross Section	69
	4.7.1 Displacement Optimization	71
	4.7.2 Blocking Force Optimization	74
	4.7.3 Energy Optimization	76
4.8	Comparison with Unimorph Actuator	78
Chapte	c 5	
Con	clusions	82
5.1	Future Work	83
Append	ix A	
Add	itional Results for Uniflex Actuator	85
A.1	Constants for Uniflex Displacement	85
A.2	Constants for Uniflex Blocking Force	86
A.3	Maximum Displacement Design	88
A.4	Maximum Displacement Design with Additional	
	Flextensional Actuator Results	91
A.5	Maximum Blocking Force Design	94
A.6	Maximum Blocking Force Design with Additional Flextensional Actu-	
	ator Results	97

Appendix B	
Additional Results for T-beam Actuator	101
Bibliography	110

# **List of Figures**

2.1	Schematic representation of the (a) PZT Unimorph Actuator at 0 V and	
	(b) at finite drive voltage V, (c) Uniflex actuator at 0 V and (d) Uniflex	
	actuator at a finite drive voltage V	9
2.2	Finite element model of uniflex actuator: (a) Initial, and (b) after deflection	10
2.3	Schematic (not to scale) illustration of the uniflex fabrication process.	11
2.4	Photograph of a fabricated unimorph.	14
2.5	Photograph of the fabricated uniflex actuator array.	15
2.6	Zygo image of a 400 $\mu$ m long flextensional actuator with (a) no bias	
	and (b) bias of 10 V. 4.16 $\mu$ m of displacement was measured. The	
	displacement is the difference in the height of the aluminum cap with	
	respect to the PZT actuator between the two cases	16
2.7	Actuator deflection as a function of applied voltage for various lengths	
	of the actuator and for (a) 1 $\mu$ m thick PZT and 1 $\mu$ m thick Al cap, (b) 1	
	$\mu$ m thick PZT and 2 $\mu$ m thick Al cap, (c) 1.4 $\mu$ m thick PZT and 1 $\mu$ m	
	thick Al cap, (d) 1.4 $\mu$ m thick PZT and 2 $\mu$ m thick Al cap	17
2.8	(a) Blocking force raw data obtained using the nanoindenter for 300 $\mu$ m	
	long actuator with 1 $\mu$ m thick PZT and 1 $\mu$ m thick Al cap. (b) The data	
	is converted into a voltage-blocking force graph showing the hysteresis	
	actuation behavior of the actuator.	19
2.9	Photograph (a) and X-X cross-section schematic of the initial (b) and	
	deflected (c) uniflex actuator.	21
2.10	Geometrically exact uniflex actuator model displacement versus clear-	
	ance $L_1$ for an actuator length $L_a=300 \ \mu m$ , rigid joint ( $K_t = \infty$ ), Alu-	
	minum cap thickness $t_a = 1 \ \mu m$ , PZT thickness $t_p = 1 \ \mu m$ , and other	
	actuator parameters shown in Tab. 2.1: $w_2(L)$ (solid line) and $w_3(0)$	
	(dashed)	30
2.11	Displacement versus actuator length $L_a$ for the four configurations of	
	the actuator: Uniflex experimental data is shown as dots, and theoretical	
	weakened joint displacement $w_2(L)$ is shown as the solid lines	32

3.1	Schematic of deflected (a) unimorph, (b) flextensional, and (c) uniflex	<b>Q</b> (
32	Actuators	36
5.2	with $t_a = 1 \ \mu m$ (solid), unimorph actuator $w_U$ (dotted), and flexten-	
	sional actuator $w_F$ with $t_a = 1 \ \mu m$ (dashed)	39
3.3	Blocking force for maximum displacement design versus actuator length: uniflex actuator $F_{UF}$ with $t_a = 1 \ \mu m$ (solid), unimorph actuator $F_U$ (dot-	
	ted), and flextensional actuator $F_F$ with $t_a = 1 \ \mu m$ (dashed)	39
3.4	Maximum displacement versus Al thickness ( $L_a = 300 \ \mu$ m): uniflex	4.1
35	$w_{UF}$ (solid), unimorph $w_U$ (dotted), and flextensional $w_F$ (dashed) Blocking force for maximum displacement design versus Al thickness	41
5.5	$(L_a = 300 \ \mu\text{m})$ : uniflex $F_{IJF}$ (solid), unimorph $F_{IJ}$ (dotted), and flexten-	
	sional $F_F$ (dashed).	41
3.6	Clearance for maximum displacement design versus Al thickness ( $L_a =$	10
37	$300 \ \mu\text{m}$ ): unifiex (solid) and flextensional (dashed)	42
5.7	with clearance $L_1 = 2.7 \ \mu m$ (solid), unimorph actuator $F_{II}$ (dotted), and	
	flextensional actuator $F_F$ with clearance $L_1 = 2.7 \ \mu \text{m}$ (dashed)	44
3.8	Displacement for maximum blocking force design versus actuator length:	
	unifiex actuator $w_{UF}$ with clearance $L_1 = 2.7 \ \mu m$ (solid), unimorph ac- tuator was (dotted), and flowtonsional actuator we with clearance $L_1 = 2.7 \ \mu m$	
	tuator $w_U$ (dotted), and nextensional actuator $w_F$ with clearance $L_1 = 2.7 \ \mu m$ (dashed).	44
3.9	Maximum blocking force versus clearance ( $L_a = 300 \ \mu$ m): uniflex ac-	
	tuator $F_{UF}$ (solid), unimorph $F_U$ (dotted), and flextensional actuator $F_F$	
3 10	(dashed)	45
5.10	$300 \ \mu\text{m}$ ): uniflex actuator $w_{IIF}$ (solid), unimorph $w_{II}$ (dotted) and flex-	
	tensional actuator $w_F$ (dashed)	46
3.11	Aluminum cap thickness $t_a$ for maximum blocking force design ver-	
	sus clearance ( $L_a = 300 \ \mu$ m): unifiex actuator (solid) and flextensional actuator (dashed)	47
		17
4.1	T-beam actuator concept: (a) As fabricated and deflected shapes when voltage is applied between (b) both flanges and bettom electrodes. (c)	
	web and bottom electrode, (d) left flange and bottom electrode, and (e)	
	right flange and bottom electrode	49
4.2	Web actuated cantilevered Tbeam: (a) Transverse deflection, and (b)	<b>5</b> 1
12	electric field	51
4.3	and in-plane (bottom)) and (b) cross section.	52

4.4	Schematic illustration of T-beam fabrication: (a) start with 1mm thick bulk PZT-4 with Cr/Au coating. (b) dice to form web regions. (c) etch	
	bottom electrodes (d) spray photoresist pattern and evaporate Cr/Au	
	for flange electrodes, (e) lift-off photoresist to form flange electrodes	
	(f) release individual T-beams by dicing	59
45	Photograph of a fabricated and mounted T-beam (Device 4) actuator	62
4.6	Photograph of experimental set-up to measure displacement and block-	62
	ing force of T-beam actuators.	63
4.7	Applied electric field $\phi$ versus free tip out of plane displacement $w_f$ for Device 3: Theoretical (solid - web actuation, dashed - flange actuation,	
	dashdot - right or left flange actuation) and experimental (star - web	
	actuation, diamond - flange actuation, square - left flange, and triangle	
	- right flange).	65
4.8	Applied electric field, $\phi$ versus in-plane tip displacement, $v_f$ for Device	
	3: theoretical (dashdot - Right flange (top), left flange (bottom)) and	
	experimental (plus - left flange, circle - right flange).	66
4.9	Applied electric field $\phi$ versus tip force, $F_3$ for Device 3: Theoretical	
	(solid - web actuation, dashed - flange actuation) and experimental (star	
	- web actuation, diamond - flange actuation)	67
4.10	Non-dimensional voltage, $V_2^*$ , $V_3^*$ , versus displacement, $v_f^*$ , $w_f^*$ , for De-	
	vices 1 - 6: Theoretical (solid) and experimental (star - web actuation,	
	diamond - flange actuation, square or plus - left flange, triangle or circle	
	- right flange actuation)	68
4.11	Non-dimensional blocking force $F_{3b}^*$ versus nondimensional voltage $V_3^*$	
	for Devices 1 to 6: Theoretical (solid) and experimental (star - web	
	actuation, diamond - flange actuation).	69
4.12	Contour plot of nondimensional displacement $(K_w)_{flange}$ versus $b^*$ and	= 0
	$t^*$ for PZT-4 material properties (Tab. 4.4)	72
4.13	Non-dimensional displacement $K_w$ versus $t^*$ for $b^*=0.381$ with PZ1-4	
	material properties for web (theoretical - solid, experimental - star) and	74
1 1 1	nange (theoretical - dashed, experimental - diamond) actuation Non-dimensional blocking former $K$ -control to $*$ and $*$	74
4.14	Non-dimensional blocking force $K_F$ versus b and t	15
4.13	Non-dimensional blocking force $K_F$ versus $t^{-1}$ for $b^{-}=0.581$ for web	
	(incorrencial - solid and experimental - star) and hange (incorrencial -	76
1 16	dashed and experimental - diamond) actuation	70 77
4.10	Non-dimensional machanical anarray $K_{E}$ versus $t^{*}$ for $b^{*}=0.281$ (theo	11
4.1/	retical black solid (web actuation) and black dashed (flenge actuation)	
	Experimental star (web actuation) and diamond (flange actuation)) and	
	Experimental - star (web actuation) and diamond (nange actuation)) and $b^* = 0.25$ (even)	79
	v = 0.25 (cyall)	10

4.18	Flange displacement coefficient $(w_c)_{flange}$ versus $b^*, t^*$	80
A.1	Clearance $L_1$ for maximum displacement versus length ( $L_a$ ): uniflex actuator with $t_a = 1 \ \mu m$ (dashed) and $t_a = 0.3 \ \mu m$ (dotted), and flexten-	00
A.2	sional actuator with $t_a = 1 \ \mu m$ (dash-double dotted)	89 90
A.3	Uniflex actuator ratio $t_p/t_b$ for maximum displacement versus Al thickness $t_a$ ( $L_a = 300 \ \mu$ m).	91
A.4	Maximum displacement versus length $L_a$ : uniflex actuator $w_2(L)$ with $t_a = 1 \ \mu m$ (dashed) and $t_a = 0.3 \ \mu m$ (dotted), unimorph actuator $w_3(0)$ (dash-dotted), and flextensional actuator $w_2(L)$ with $t_a = 1 \ \mu m$ (dash-	
A.5	double dotted) and $t_a = 0.3 \ \mu \text{m}$ (double dash-dotted) Blocking force <i>F</i> for maximum displacement configuration versus length $L_a$ : unifiex actuator with $t_a = 1 \ \mu \text{m}$ (dashed) and $t_a = 0.3 \ \mu \text{m}$ (dotted), unimorph actuator (dash-dotted), and flextensional actuator with	92 ∎
A.6	$t_a = 1 \ \mu \text{m}$ (dash-double dotted) and $t_a = 0.3 \ \mu \text{m}$ (double dash-dotted). Clearance $L_1$ for maximum displacement versus length $L_a$ : uniflex actuator with $t_a = 1 \ \mu \text{m}$ (dashed) and $t_a = 0.3 \ \mu \text{m}$ (dotted), and flextensional actuator with $t_a = 1 \ \mu \text{m}$ (dash-double dotted) and $t_a = 0.3 \ \mu \text{m}$ (double	93
A.7	dash-dotted)	94
A.8	Ratio $t_p/t_b$ for maximum blocking force versus length $L_a$ : uniflex actuator with clearance $L_1 = 2.7 \ \mu m$ (dashed) and $L_1 = 40 \ \mu m$ (dotted), and unimorph actuator (dash-dotted).	96
A.9	Uniflex actuator ratio $t_p/t_b$ for maximum blocking force versus clear- ance $L_1$ for $L_a = 300 \ \mu\text{m}$ .	97
A.10	Maximum blocking force $F$ versus length $L_a$ : uniflex actuator with clearance $L_1 = 2.7 \ \mu m$ (dashed) and $L_1 = 40 \ \mu m$ (dotted), unimorph actuator (dash-dotted), and flextensional actuator with $L_1 = 2.7 \ \mu m$ (dash-	
A.11	double dotted) and $L_1 = 40 \ \mu m$ (double dash-dotted) Displacement for maximum blocking force configuration versus length $L_a$ : uniflex $w_2(L)$ with clearance $L_1 = 2.7 \ \mu m$ (dashed) and $L_1 = 40 \ \mu m$ (dotted), unimorph actuator $w_3(0)$ (dash-dotted), and flextensional actuator $w_2(L)$ with $L_4 = 2.7 \ \mu m$ (dash-double dotted) and $L_4 = 40 \ \mu m$	98
	(double dash-dotted)	99

A.12	2 Al thickness $t_a$ for maximum blocking force versus length $L_a$ : uniflex with clearance $L_1 = 2.7 \ \mu \text{m}$ (dashed) and $L_1 = 40 \ \mu \text{m}$ (dotted), and flextensional actuator with clearance $L_1 = 2.7 \ \mu \text{m}$ (dash-double dotted) and $L_1 = 40 \ \mu \text{m}$ (double dash-dotted).	100
B.1	Applied electric field $\phi$ versus free tip out of plane displacement $w_f$ for Device 1: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle	
B.2	- right flange)	102
	$v_f$ for Device 1: theoretical (dashdot - Right flange (top), left flange	100
B.3	(bottom)) and experimental (plus - left flange, circle - right flange) Applied electric field $\phi$ versus tip force, $F_3$ for Device 1: Theoretical	102
	(solid - web actuation, dashed - flange actuation) and experimental (star	103
B.4	Applied electric field $\phi$ versus free tip out of plane displacement $w_f$ for	105
	Device 2: Theoretical (solid - web actuation, dashed - flange actuation, dashed - right or laft flange actuation) and experimental (star - web	
	actuation, diamond - flange actuation, square - left flange, and triangle	
D 5	- right flange).	103
Б.Ј	$v_f$ for Device 2: theoretical (dashdot - Right flange (top), left flange	
D 6	(bottom)) and experimental (plus - left flange, circle - right flange)	104
<b>D</b> .0	(solid - web actuation, dashed - flange actuation) and experimental (star	
	- web actuation, diamond - flange actuation)	104
B.7	Applied electric field $\phi$ versus free tip out of plane displacement $w_f$ for Device 4. Theoretical (solid - web actuation dashed - flange actuation	
	dashdot - right or left flange actuation) and experimental (star - web	
	actuation, diamond - flange actuation, square - left flange, and triangle	105
B.8	Applied electric field, $\phi$ versus in-plane displacement tip displacement,	105
	$v_f$ for Device 4: theoretical (dashdot - Right flange (top), left flange	
RÛ	(bottom)) and experimental (plus - left flange, circle - right flange) Applied electric field $\phi$ versus tip force $E_2$ for Device 4: Theoretical	105
י.ע	(solid - web actuation, dashed - flange actuation) and experimental (star	
	- web actuation, diamond - flange actuation)	106

<b>B</b> .10	Applied electric field $\phi$ versus free tip out of plane displacement $w_f$ for	
	Device 5: Theoretical (solid - web actuation, dashed - flange actuation,	
	dashdot - right or left flange actuation) and experimental (star - web	
	actuation, diamond - flange actuation, square - left flange, and triangle	
	- right flange)	106
<b>B</b> .11	Applied electric field, $\phi$ versus in-plane displacement tip displacement,	
	$v_f$ for Device 5: theoretical (dashdot - Right flange (top), left flange	
	(bottom)) and experimental (plus - left flange, circle - right flange)	107
B.12	Applied electric field $\phi$ versus tip force, $F_3$ for Device 5: Theoretical	
	(solid - web actuation, dashed - flange actuation) and experimental (star	
	- web actuation, diamond - flange actuation)	107
B.13	Applied electric field $\phi$ versus free tip out of plane displacement $w_f$ for	
	Device 16: Theoretical (solid - web actuation, dashed - flange actuation,	
	dashdot - right or left flange actuation) and experimental (star - web	
	actuation, diamond - flange actuation, square - left flange, and triangle	
	- right flange).	108
<b>B</b> .14	Applied electric field, $\phi$ versus in-plane displacement tip displacement,	
	$v_f$ for Device 6: theoretical (dashdot - Right flange (top), left flange	
	(bottom)) and experimental (plus - left flange, circle - right flange)	108
B.15	Applied electric field $\phi$ versus tip force, $F_3$ for Device 6: Theoretical	
	(solid - web actuation, dashed - flange actuation) and experimental (star	
	- web actuation, diamond - flange actuation)	109

# List of Tables

2.1	Parameters for uniflex actuator	27
2.2	Uniflex actuator blocking force experimental data and theoretical pre-	
	dictions	33
2.3	Uniflex* actuator displacement amplification over unimorph actuator	
	for PZT thickness $t_p = 1.4 \ \mu m$ , Si <sub>3</sub> N <sub>4</sub> thickness $t_b = 1 \ \mu m$ , and Alu-	
	minum thickness* $t_a = 1 \ \mu m$ at 10 V	33
4.1	Electromechanical coefficients for web and flange actuation	54
4.2	Cross-sectional area, first moment of area, and second moment of area	
	for web, flange and, single flange actuation	56
4.3	Fabricated prototype parameters	61
44	P7T 1 material properties	64
		04

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Chapter 1 \_\_\_\_\_

## Introduction

The past few years have seen significant improvement in the commercial applications for electro-mechanical actuators. Piezoelectric electro-mechanical actuators provide a seamless way to convert electrical and mechanical energy back and forth thereby, providing lot of scope, for energy harvesting and actuation.

The challenge of piezoelectric actuation is the amplification of small strain (0.1%) to produce reasonable displacement. Most piezoelectric actuators use Lead Zirconate Titanate (PZT) because it provides large piezoelectric and electro-mechanical coupling factors [1, 2]. To produce reasonable motion, however, the piezoelectric strain must be amplified. Several amplification mechanisms are studied by various researchers. Some of the designs and their applications are presented in the following sections.

#### **1.1** Applications

Piezoelectric actuators are extensively used in commercial products at the macroscale. High performance V-stack actuators are used for control of high aspect ratio wings in uninhabited air vehicles [3]. Properly designed actuators provide active control of helicoptor rotors with improved vibration control and stability[4, 5, 6, 7, 8]. Naval applications like low frequency piezoelectric SONAR devices having lower weight and higher portability are reported in [9]. Piezoelectric actuators are also used in adaptive optics to produce deformable mirrors [10] because of its low voltage actuation and capability of miniaturization. Piezoelectric actuated auto focus lenses enable scanners to read the barcode at much longer distances [11, 12].

Micro-feed stages and multi degree of freedom micro manipulators driven by piezoelectric actuators enable ultra-precision positioning of 0.001 to 0.01  $\mu$ m because of their fine displacement resolution and no friction [13, 14]. There is a lot of research going on for application to acoustic transducers like microphone and micro speakers [15, 16]. The piezoelectric cantilevered microphones are found to be more sensitive and stress free when compared to the conventional microphones [17, 18]. Disk type piezoelectric actuators have wide applications in micro pumps for micro pump driver [19] and fuel drop generation in automobiles [20]. Recently, piezoelectric cymbal actuators are reported for micro-flow applications [21]. Cantilevered piezoelectric unimoprh actuators are extensively used in RF switches [22, 23, 24] because of better isolation and low insertion loss from DC to 50 GHz.

#### **1.2 Macroactuators**

Various designs are invented by different researchers to enable reasonable strain amplification and also obtain required blocking force. Stack actuators [25, 26, 27] produce larger motions at low voltages by stacking electroded thin PZT disks and actuating through the thickness. In this case, the material poling, applied voltage and displacement are all in the same direction. Adjacent disks have opposite poling and field directions. This makes use of the  $d_{33}$  piezoelectric coefficient which is much larger than the  $d_{31}$ coefficient (~1/3 of  $d_{33}$ ) used in unimorph or bimorph actuators. The stack actuators are modeled [27, 28], compared [25], optimized for maximum energy output [26], and to many specific applications like V-stack actuator [3]. Further displacement amplification with four bar linkages and stack actuators are capable of producing very high force but displacement is limited by number of layers that can be fabricated to operate at reasonable voltages and size of actuator.

Unimorph actuators use the compliant bending mechanism to amplify the displacement, using the  $d_{31}$  piezoelectric coefficient [27, 31]. The unimorph has a PZT layer poled through the thickness and a passive layer bonded to it. The PZT layer expands through the thickness and contracts longitudinally when an electric field is applied in the poling direction between the electrodes placed on top and bottom of piezoelectric layer. The longitudinal contraction causes the unimorph to bend due to the constraining passive layer (like silicon nitride). Static and dynamic models to predict displacement, blocking force, resonant frequencies [27, 32], and electro-mechanical coupling factors and output efficiencies [31, 33] are studied by various researchers.

To improve the displacement further, both the layers of unimorph can be made of active piezoelectric material, polarized in the same direction. For one of the layers the voltage is applied in the direction of poling and opposite for another layer. The first layer contracts while the second layer expands in length resulting in very high transverse displacement [27, 32]. The maximum applied field in the opposite direction of poling is limited to  $\sim$ 1/3 of the positive field to prevent depoling of the PZT. The force produced by such a structure is higher than the unimorph alone for the same applied field. Also, multimorphs consisting of cantilevers with multiple layers of PZT and passive layers are also reported [34, 35, 36]. Tube actuators that produce bimorph actuation in two directions have been demonstrated at the macroscale [37].

Flextensional actuators [38, 39] have a bulk PZT with a metallic cap bonded at the ends. When the PZT is actuated, the  $d_{31}$  actuation causes the bulk PZT to contract in length and the cap flexes producing displacement. One of such popular macroscale actuator is flextensional Moonie actuator which uses the flexural motion of the cap [38], whereas the cymbal actuator uses both flexural and rotation motions [40, 41, 42]. Cymbal actuators are also fabricated with lead free piezo-ceramic materials [43, 44, 45]. Displacement, resonance frequency [46, 47] and the effective piezoelectric coefficient [48] characteristics of these actuators are extensively studied. Some researchers used topology optimization to obtain optimum flextensional designs for displacement and

blocking output [49].

Another kind of novel actuator called "drum actuator" consists of a circular disc, with brass membrane attached at the circular end as in a drum. PZT layer is attached to the brass membrane and when actuated produces flexural motion of brass and PZT layers using  $d_{31}$  piezoelectric coefficient [50, 51].

#### **1.3 Microactuators**

At the microscale, however, piezoelectric actuators are difficult to fabricate. Although solder bonding techniques for PZT have been reported [52] stack actuators of more than a few layers have not been fabricated.

Some researchers used low performance AlN or ZnO piezoelectric materials [53] to produce flextensional actuators. These micro-scale flexensional actuators can operate in ultrasound frequencies unlike their macro scale counter parts [54]. Considerable analytical and experimental research is done about the applicability of these micro flextensional actuators to ultrasound [55, 56] and high resolution ink-jet printing applications [53, 57] using the thin plate theory and Mindlin plate theory.

Recently, using thin film and solder bonding techniques, researchers have fabricated microscale piezoelectric unimorph [32] and flextensional [58] actuators. Thin film PZT actuators are successfully implemented for precision alignment of fibre-optic cables [59] and circular unimorph disks for micropump applications [60]. There is also considerable interest in fabricating piezoelectric thin film actuators using micromachining [61, 62].

Micromachined cantilevered unimorph and bimorhs are extensively studied for RF applications [63, 64]. Micromchined multimorphs are explored for micro-optic applications [65]. Conventional silicon chip manufacturing process uses spinning to deposit photoresists. To reduce the wastage during the process, micro machined acutators are studied for spinless resist deposition [66]

The PZT thin films that have been demonstrated, however, do not have the quality of bulk PZT [67] and stress mismatch between the layers during the fabrication, results in variably defected structures upon release. So the performance of piezoelectric microactuators can be improved. Also novel designs that can further amplify displacement will greatly increase the applicability of these actuators.

### **1.4 Current Research**

This research describes the design, modeling, and optimization of a piezoelectric uniflex microactuator and a T-beam actuator. The uniflex actuator combines the actuation mechanisms of a unimorph and flextensional actuator. A flexural aluminum cap is attached at the ends of a unimorph to form a uniflex actuator. The unimorph bends and the cap flexes to amplify the small strain of piezoelectric material and produce relatively large displacement. Prototypes are fabricated using photolithography and thin film deposition techniques. Physics based analytical models are developed to predict displacement and blocking force as functions of the applied voltage and force. The models are validated against the experimental data[68]. The uniflex designs that maximize displacement and blocking force are discussed in detail based on experimentally validated models.

Also, this research introduces a novel monolithic microactuator that can be fabricated from bulk PZT by micro-machining using an Inductive Coupled Plasma-Reactive Ion Etching (ICP- RIE) [69] or by dicing. Using this process, a two axis unimorph can be fabricated from a bulk PZT wafer. This T-beam actuator is fabricated and experimentally shown to produce both out-of-plane and inplane displacements. Analytical models are built to predict the displacement and blocking force and validated using experimental models. Prototypes are fabricated using dicing for detailed parametric studies. Modelbased analysis shows that the T-beam actuator geometry can be optimized to produce large displacement and blocking force. Specific configurations that maximize displacement, blocking force, and mechanical energy are discussed in detail.

#### **1.5** Organization of the Dissertation

Chapter 2 discusses about the design, fabrication, and modeling of uniflex microactuator. Chapter 3 discusses in the detail the optimization of uniflex actuator. Chapter 4 introduces the concept of novel T-beam micro-actuator. Analytical modeling, experimental validation and optimization are discussed in detail. Chapter 5 concludes with the results from uniflex and T-beam actuators analysis. Also, future research ideas are presented.



# Design, Fabrication, and

# **Performance of a Piezoelectric**

## **Uniflex Microactuator**

## 2.1 Introduction

In this chapter the design, fabrication and performance of piezoelectric microactuator is discussed. The uniflex actuator combines the amplification methods of unimorph and flextensional actuators. The unimorph bends and the cap flexes to amplify the small strain of piezoelectric material and produce relatively large displacements. A detailed model that predicts the displacement and blocking force of uniflex actuators as a function of the applied voltage is presented.



**Figure 2.1.** Schematic representation of the (a) PZT Unimorph Actuator at 0 V and (b) at finite drive voltage V, (c) Uniflex actuator at 0 V and (d) Uniflex actuator at a finite drive voltage V.

### 2.2 The Uniflex Actuator

Fig. 2.1(a and b) illustrate schematically the construction and operation of unimorph actuator. The unimorph actuator has a bottom layer of passive  $Si_xN_y$  and a top layer of PbZr<sub>0.52</sub>Ti<sub>0.48</sub>O<sub>3</sub> (PZT). The PZT is poled through the thickness and electroded on top and bottom. Voltage is applied in the poling direction, causing  $d_{31}$  contraction of the PZT and upward bending of the unimorph. Fig. 2.1(c and d) show a schematic diagram of a uniflex actuator. The uniflex actuator consists of a unimorph that is supported by a bridge structure at the center and an Al cap that is bonded at the ends of the unimorph. The Al cap is bent away from the unimorph such that there is a small gap between the cap and unimorph over most of the length. When the unimorph is actuated, the Al cap is compressed by the unimorph and, if correctly designed, buckles upward. Thus, the uniflex actuator combines unimorph and flexural displacement amplification mech-



Figure 2.2. Finite element model of uniflex actuator: (a) Initial, and (b) after deflection.

anisms to produce large vertical displacement at the center of the Al cap. Figure 2.2(a) shows the two dimensional half sector finite element model of uniflex actuator. ANSYS PLANE13 coupled field elements are used to model the active piezoelectric material (PZT). PLANE 42 elements with plane stress option are used to model the base silicon nitride of unimorph and the flexural aluminum cap. Aluminum cap is attached to the unimorph by writing the coupling equations  $(u_x)_{Al} = (u_x)_{PZT}$ , and  $(u_y)_{Al} = (u_y)_{PZT}$  at the interface (shown in light green), where  $u_x$  and  $u_y$  are the deflections in horizontal and vertical directions. Reflective symmetry boundary conditions are applied at the right end for both unimorph, and aluminum cap. Figure 2.2(b) shows the deflected shape of uniflex actuator when voltage is applied between top and bottom layers of PZT. The deflected configuration shows that uniflex design works as expected.



**Figure 2.3.** Schematic (not to scale) illustration of the fabrication process. Cross-sectional view corresponds to the dotted line on top view. (a) Deposit PolySi/SiO<sub>2</sub>-Si<sub>3</sub>N<sub>4</sub>-SiO<sub>2</sub>/Ti-Pt/PZT/Cr-Au, (b) Apply photoresist and pattern the PZT unimorph stack and RIE etch through PolySi, (c) Apply photoresist and pattern Cr-Au layer for top electrode via wet etching, (d) Deposit 2.7  $\mu$ m thick photoresist (Shipley 1827) for sacrificial layer and pattern, (e) Deposit Al for cap structure, pattern, and etch, (f) Pattern photoresist to prevent unwanted undercutting during release step, (g) Release actuator structure using XeF<sub>2</sub> isotropic etching while other surfaces are covered by photoresist for protection from XeF<sub>2</sub>, (h) Release flexural (Al cap) structure with acetone/IPA/Methanol.

## 2.3 Fabrication of the Uniflex Actuator

The micromachined uniflex actuator uses a PZT unimorph actuator as the active element with a secondary metal flexural element. The major fabrication process steps shown in Fig. 2.3 include (i) the preparation of substrate wafers, (ii) deposition of the PZT film, (iii) patterning the active structure, (iv) fabrication of the metal flexural structure, and (v) the final release. A total of five photolithographic steps were used in the fabrication of the uniflex microactuator.

On single side polished, (100) silicon wafers, the stack of sacrificial and structural layers were deposited as follows (i) 0.5  $\mu$ m thick polysilicon (low pressure chemical vapor deposition (LPCVD) process using SiH<sub>4</sub> at 620 °C for 2 hours) as sacrificial layer, (ii) 0.1  $\mu$ m thick silicon oxide (plasma enhanced chemical vapor deposition (PECVD) using N<sub>2</sub>, SiH<sub>4</sub>, and N<sub>2</sub>O, radio frequency (RF) power of 300 W at 2 Torr, 400 °C) as protection layer, (iii) 0.8  $\mu$ m thick low stress (~ 200 MPa tensile) silicon nitride (LPCVD using SiCl<sub>2</sub>H<sub>2</sub> and NH<sub>3</sub>, 170 mTorr; 850 °C, 4 hours) as the passive unimorph layer, (iv) 0.1  $\mu$ m thick silicon oxide (plasma enhanced chemical vapor deposition (PECVD) using N<sub>2</sub>, SiH<sub>4</sub>, and N<sub>2</sub>O, RF power of 300 W at 2 Torr, 400  $^{\circ}$ C) as adhesion promotion layer and (v) 20nm/100nm thick Ti/Pt (sputtered at 300 °C with RF/direct current power of 200 W at 5 mTorr) as bottom electrode layer were deposited in the sequence described. Sol-gel lead zirconate titanante (PZT) with Zr/Ti ratio of 52/48 (PZT solution was spun at 1500 rpm for 30 seconds and two pyrolysis steps at 300 °C and 450 °C for 60 seconds each followed by 60 seconds crystallization at 700 °C resulting in a 0.2  $\mu$ m thick PZT film) were used as the active unimorph layer. Several repetitions of these steps are required to obtain the desired thickness. A complete description of the preparation and characterization of the PZT films is given elsewhere [70]. After the deposition of the PZT film, 20 nm/200 nm thick Cr/Au (electron beam evaporation at  $10^{-7}$  Torr) as top electrode layer completed the stack formation.

The first photolithography step is the patterning of photoresist for the definition of the unimorph structure in PZT. An electroplated nickel mask was used for this etching of the entire stack down to the silicon substrate using an inductively coupled plasma reactive ion etch (ICP RIE) process. In the physical etching mode, the ICP RIE etched PZT at a rate of 0.17 to 0.2  $\mu$ m/min, with the condition of 2000 W and 475 W for the source and substrate powers respectively with an Ar flow rate of 50 sccm. By adding 10 sccm of SF<sub>6</sub>, the etch rate could be increased by ~0.4  $\mu$ m/min [71]. Shipley 1827 and benzocyclobutene (BCB) photoresists can be used for masking when only Ar gas was used but in our work we found that the these masks could not reliably withstand the 5-10 minute etch process upon the addition of 10% SF<sub>6</sub>. Therefore, we used Ni hard mask which provided better yield as well as selectivity with respect to etching the stack. This was followed by the patterning of the top Cr/Au electrode using standard wet etching method.

For fabrication of the flexural structure, Shipley 1827 positive photoresist was chosen as the sacrificial material and thus only resist exposure and development steps were required. The thickness of this sacrificial photoresist layer was 2.7  $\mu$ m. This was followed by the sputtering of required thickness of aluminum and the final lithography step to define the flexural element. Aluminum was wet etched. The device was once again spin coated with photoresist and a protection mask was used to open up areas to be etched in XeF<sub>2</sub> vapor phase etching as shown in 2.3(f). The uniflex structure was released by isotropically etching polysilicon and substrate as shown schematically



Figure 2.4. Photograph of a fabricated unimorph.

in 2.3(g). The use of polysilicon sacrificial layer, which etches much more rapidly in  $XeF_2$  than single crystal substrate silicon, coupled with the photoresist protection mask prevented excessive lateral undercutting of the anchor areas and guaranteed complete release of the actuator structure with a relatively short etch time in  $XeF_2$ . The sacrificial and protective layers of photoresist were finally removed in acetone followed by an IPA/methanol rinse for achieving stiction free release. Figures 2.4 and 2.5 show the fabricated unimorph and uniflex devices.

### 2.4 Uniflex Actuator Performance

After fabrication and release, the devices were placed in a dual in-line package (DIP). Electrical connections were made via conventional ball wire bonding, and the packaged MEMS were mounted in a zero insertion force (ZIF) socket. Uniflex actuators with two different thicknesses of the PZT layer (1  $\mu$ m and 1.4  $\mu$ m) and aluminum caps layer (1



Figure 2.5. Photograph of the fabricated uniflex actuator array.

 $\mu$ m and 2  $\mu$ m) resulting in 4 different configurations were fabricated. 200, 300, 400 and 500  $\mu$ m long uniflex actuators in each configuration were measured for their static deflection and blocking force characteristics. These measurements were accomplished using a white light interferometer and a nanoindenter and are described in detail.

#### 2.4.1 Static Displacement Measurement

Measurements of the static displacement as a function of applied voltage were performed using a Zygo NT-100 white light interference microscope. Prior to making any displacement measurements, the devices were poled using 10 V (equivalent to 100 kV/cm) for 20 mins and were actuated 5 to 6 times to remove any initial hysteresis. The effectiveness of this treatment was based upon achieving stable and reproducible voltage deflection curves from the actuators. Stable displacement curves as a function of voltage in the 0 - 10 V range in 1 V steps for each uniflex length were obtained for both increasing and decreasing voltage cycles. Figure 2.6 shows the initial and the actuated shape of



**Figure 2.6.** Zygo image of a 400  $\mu$ m long flextensional actuator with (a) no bias and (b) bias of 10 V. 4.16  $\mu$ m of displacement was measured. The displacement is the difference in the height of the aluminum cap with respect to the PZT actuator between the two cases.

a 400  $\mu$ m long flextensional actuator with 1  $\mu$ m thick PZT and 1  $\mu$ m thick aluminum cap configuration. It shows that the released structure has an initial curvature due to the larger tensile stress in the PZT layer in comparison to the 0.8  $\mu$ m thick low-stress silicon nitride passive layer. Deflection of the actuator was measured as the position of the top of the aluminum cap with respect to the PZT unimorph actuator at the mid-point of the structure (point of maximum deflection). This definition of deflection makes it



**Figure 2.7.** Actuator deflection as a function of applied voltage for various lengths of the actuator and for (a) 1  $\mu$ m thick PZT and 1  $\mu$ m thick Al cap, (b) 1  $\mu$ m thick PZT and 2  $\mu$ m thick Al cap, (c) 1.4  $\mu$ m thick PZT and 1  $\mu$ m thick Al cap, (d) 1.4  $\mu$ m thick PZT and 2  $\mu$ m thick Al cap.

impervious to any offsets or motion of the freestanding anchor point of the actuator. For the device shown in Fig. 2.6, a displacement of 4.16  $\mu$ m was obtained for 10 V applied bias.

Figure 2.7 shows the deflection curves for the four configurations and for the four lengths of the actuators. As expected, the deflection of all the actuators shows a linear dependence on the drive voltage except for two actuators in Fig. 2.7(a). This unusual deflection characteristics might be due to material imperfections in the PZT films or due to unanticipated structural deflects in these specific actuators.

#### 2.4.2 Blocking Force Measurement

The blocking force measurements were performed in a Hysitron, Inc. TriboIndenter operating in laboratory air ( $\sim 22\pm2$  °C,  $\sim 50$  % R.H.). Electrical connections to the devices (via the ZIF socket) were routed through the TriboIndenter acoustic housing to insure a low vibration environment during testing. Prior to testing, the positions of the samples were identified in the optical video image, and the coordinates of the ends of the flexures were noted ( $\pm 2 \mu$ m, typical). The positions of the centers of the devices were then calculated, thereby insuring precise alignment of the measurement location. Initial poling of devices was then performed at  $3E_c$  (7.5 V) for 20 minutes with an Agilent E3612A DC power supply. A 500 nm radius, diamond, spheroconical indenter was then placed on the surface of the aluminum flexure with a contact force of 1.5  $\mu$ N. The use of a large, blunt indenter insured that contact between the tip and the device did not induce damage. The TriboIndenter was then allowed to stabilize for 1 hour to minimize the effects of thermal drift on measurement accuracy.

After stabilization, a series of blocking force measurements were performed. The TriboIndenter was used to apply a displacement-controlled, trapezoidal waveform, and the blocking force measurements were made during the constant position portion of the test. At the start of each test, the thermal drift in the system was monitored for 60 seconds, and a least squares, linear fit of the drift rate for the last 30 seconds of the monitoring period was used to correct all data (typical drift rates were  $\sim 0.005$  nm/s with a maximum allowable rate of 0.1 nm/s). The indenter tip was then linearly ramped at



**Figure 2.8.** (a) Blocking force raw data obtained using the nanoindenter for 300  $\mu$ m long actuator with 1  $\mu$ m thick PZT and 1  $\mu$ m thick Al cap. (b) The data is converted into a voltage-blocking force graph showing the hysteresis actuation behavior of the actuator.

2.5 nm/s to an initial displacement of 25 nm. This linear ramp was followed by a 40, 70, 130, or 250 second period where the position was held constant. During this hold period a 0 to 10 V, triangular ramp waveform at 34 mHz was applied with an Agilent 33120A arbitrary waveform generator. The number of applied voltage cycles was 1, 2, 4, and 8 for the 40, 70, 130, and 250 second hold periods, respectively. Figure 2.8(a) shows the raw blocking force data obtained as a function of time for actuator 300  $\mu$ m long actuator

with 1  $\mu$ m thick PZT and 1  $\mu$ m thick Al cap. This data is converted into a voltage versus blocking force data as shown in Fig. 2.8(b). The hold period was then followed by the withdrawal of the diamond tip at a rate of 2.5 nm/s. The force and displacement data were measured continuously throughout the test with the personal computer controlled data acquisition system, and were saved to file for evaluation.

### 2.5 Mathematical Modeling

The uniflex actuator shown in Fig. 2.9(a) is modeled as an assembly of beams 1, 2, and 3 as shown in Fig. 2.9(b). Beam 3 is the unimorph and beams 1 and 2 are the support leg and span of the aluminum cap, respectively. We assume symmetric loading (mid-span point load), so a half span model with a reflective symmetric boundary condition at the right boundary of the cap is used. The cartesian coordinates,  $x_i$  and  $z_i$  (i = 1, 2, 3) shown in Fig. 2.9(b) denote the horizontal and vertical positions of the material particles, for the three beams. Figure 2.9(c) shows the deflected structure with centroidal displacements  $u_i$  and  $w_i$  in the  $x_i$  and  $z_i$  directions, respectively. The thickness dimensions  $t_a$ ,  $t_p$  and  $t_b$  correspond to the Al cap, PZT, and Si<sub>x</sub>N<sub>y</sub>, respectively. Beams 3 and 2 have length L and  $L_1$  is the length of beam 1 or the clearance between beam 2 and beam 3. The actuator length  $L_a = 2L + 40 \ \mu$ m includes the 20  $\ \mu$ m clamped region at the ends of the structure that contribute to the length of the actuator but not the displacement.

The three beams have eighteen boundary conditions. Beam 3 is clamped at the right end and fixed via a torsional spring of stiffness  $K_t$  at the left end to beam 1. Geometri-


**Figure 2.9.** Photograph (a) and X-X cross-section schematic of the initial (b) and deflected (c) uniflex actuator.

cally exact modeling of the uniflex actuator requires a rigid connection between beams 1 and 3 or  $K_t = \infty$ . However, the weakened connection associated with  $K_t < \infty$  is found to more accurately predict the experimentally measured displacement and blocking force of the uniflex actuator. Beam 2 is clamped to beam 1 at the left end and guided at the right end. The governing equations and the boundary conditions for static operation are obtained using the principle of virtual work. The potential energy for the structure is [32]

$$U_{1} = \int_{V_{1}} \frac{E_{1}}{2} \left( \frac{\partial w_{1}(z_{1})}{\partial z_{1}} - x_{1} \left( \frac{\partial^{2} u_{1}(z_{1})}{\partial z_{1}^{2}} \right) \right)^{2} dV,$$

$$U_{2} = \int_{V_{2}} \frac{E_{2}}{2} \left( \frac{\partial u_{2}(x_{2})}{\partial x_{2}} - z_{2} \left( \frac{\partial^{2} w_{2}(x_{2})}{\partial x_{2}^{2}} \right) \right)^{2} dV,$$

$$U_{3} = \int_{V_{b}} \frac{E_{b}}{2} \left( \frac{\partial u_{3}(x_{3})}{\partial x_{3}} - z_{3} \left( \frac{\partial^{2} w_{3}(x_{3})}{\partial x_{3}^{2}} \right) \right)^{2} dV$$

$$+ \int_{V_{p}} H dV,$$

$$U_{\text{TS}} = \frac{K_{t}}{2} \left( \frac{dw_{1}(0)}{dx_{1}} - \frac{du_{1}(0)}{dz_{1}} \right)^{2},$$

$$U = U_{1} + U_{2} + U_{3} + U_{\text{TS}},$$
(2.1)

where  $E_1 = E_2$ ,  $E_p$  and  $E_b$  are the Young's moduli of Al, PZT and Si<sub>x</sub>N<sub>y</sub>, respectively, $V_1$ ,  $V_2$ ,  $V_p$  and  $V_b$  are volumes of beam 1, beam 2, PZT and Si<sub>x</sub>N<sub>y</sub> layers of beam 3, respectively,  $U_1$ ,  $U_2$ ,  $U_3$ ,  $U_{TS}$  are the potential energy of beam 1, beam 2, beam 3, and the torsional spring, respectively, and U is the total potential energy of the actuator. The

electric enthalpy H for the piezoelectric material is [32]

$$H = \frac{E_p}{2} \left( \frac{\partial u_3(x_3)}{\partial x_3} \right)^2 + \frac{e_{31}V}{2t_p} \frac{\partial u_3(x_3)}{\partial x_3} + \left( \frac{1}{2} \left[ E_p + \frac{e_{31}^2}{\varepsilon_{33}} \right] z_3^2 - \frac{e_{31}^2(2e - t_p)^2}{8\varepsilon_{33}} \right) \left( \frac{\partial^2 w_3(x_3)}{\partial x_3^2} \right)^2 - \frac{e_{31}V}{2t_p} (2e - t_p) \frac{\partial^2 w_3(x_3)}{\partial x_3^2} - \frac{\varepsilon_{33}V^2}{2t_p^2} + \left( \frac{e_{31}^2(2e - t_p)}{2\varepsilon_{33}} - \left[ E_p + \frac{e_{31}^2}{\varepsilon_{33}} \right] z_3 \right) \frac{\partial^2 w_3(x_3)}{\partial x_3^2} \frac{\partial u_3(x_3)}{\partial x_3},$$
(2.2)

where  $e_{31}$  is piezoelectric stress coefficient,  $\varepsilon_{33}$  is the permittivity of PZT, V is the potential difference between top and bottom layers of PZT, and *e* is the distance between the centroid of beam 3 and the PZT/Si<sub>x</sub>N<sub>y</sub> interface [32] given by

$$e = \left(\frac{t_b}{2}\right) \left(\frac{\frac{E_b}{E_p} - \left(\frac{t_p}{t_b}\right)^2}{\frac{E_b}{E_p} + \frac{t_p}{t_b}}\right).$$
(2.3)

Substitution of Eqs. (2.1) into the principal of virtual work,  $\int_{0}^{t} (\delta U + F \delta u_2(L,t)) dt = 0$ , produces the boundary conditions and field equations

$$\frac{d^2 w_1(z_1)}{dz_1^2} = 0, \ \frac{d^4 u_1(z_1)}{dz_1^4} = 0, \ \forall \ z_1 \in (0, L_1),$$
(2.4a)

$$\frac{dz_1}{dx_2^2} = 0, \ \frac{d^4w_2(x_2)}{dx_2^4} = 0, \ \forall x_2 \in (0,L),$$
(2.4b)

$$\frac{d^2 u_3(x_3)}{dx_3^2} = 0, \ \frac{d^4 w_3(x_3)}{dx_3^4} = 0, \ \forall \ x_3 \in (0,L) \,.$$
(2.4c)

The natural and geometric boundary conditions at joint **a-b** are

$$w_{1}(0) = w_{3}(0), \ u_{1}(0) = u_{3}(0) - \delta \frac{dw_{3}(0)}{dx_{3}},$$

$$-E_{1}A_{1}\frac{dw_{1}(0)}{dz_{1}} + (E_{b}I_{be} + 2a_{2}I_{pe} + 2a_{3}A_{p})\frac{d^{3}w_{3}(0)}{dx_{3}^{3}} = 0,$$

$$E_{1}I_{1}\frac{d^{3}u_{1}(0)}{dz_{1}^{3}} - \left[(E_{b}A_{b} + E_{p}A_{p})\frac{du_{3}(0)}{dx_{3}} + a_{8}A_{p}\right] = 0,$$

$$K_{t}\left(\frac{dw_{3}(0)}{dx_{3}} + \frac{du_{1}(0)}{dz_{1}}\right) - \delta E_{1}I_{1}\frac{d^{3}u_{1}(0)}{dz_{1}^{3}} - \left[(E_{b}I_{be} + 2a_{2}I_{pe} + 2a_{3}A_{p})\frac{d^{2}w_{3}(0)}{dx_{3}^{2}} + a_{4}A_{p}\right] = 0,$$

$$K_{t}\left(\frac{dw_{3}(0)}{dx_{3}} + \frac{du_{1}(0)}{dz_{1}}\right) - E_{1}I_{1}\frac{d^{2}u_{1}(0)}{dz_{1}^{2}} = 0,$$
(2.5)

where  $\delta$  is the length of rigid link **a-b**,  $I_1$  is the moment of inertia of beam 1,  $I_{be}$  and  $I_{pe}$  are moment of inertia for Si<sub>x</sub>N<sub>y</sub> and PZT of beam 3, and  $A_b$  and  $A_p$  are the crosssectional areas of Si<sub>x</sub>N<sub>y</sub> and PZT, respectively. The electro-mechanical factors  $a_2$ ,  $a_3$ ,  $a_4$  and  $a_8$  are given by

$$a_{2} = \frac{1}{2} \left( E_{p} + \frac{e_{31}^{2}}{\varepsilon_{33}} \right), a_{3} = \frac{-e_{31}^{2} \left( 2e + t_{p} \right)^{2}}{8\varepsilon_{33}},$$

$$a_{4} = -\frac{e_{31} \left( 2e + t_{p} \right) V}{2t_{p}}, a_{8} = e_{31} \frac{V}{t_{p}}.$$
(2.6)

The boundary conditions at rigid joint **c** are

$$w_{1}(L_{1}) = w_{2}(0), \ u_{1}(L_{1}) = u_{2}(0),$$

$$-\frac{du_{1}(L_{1})}{dz_{1}} = \frac{dw_{2}(0)}{dx_{2}},$$

$$E_{1}A_{1}\frac{dw_{1}(L_{1})}{dz_{1}} + E_{2}I_{2}\frac{d^{3}w_{2}(0)}{dx_{2}^{3}} = 0,$$

$$-E_{1}I_{1}\frac{d^{3}u_{1}(L_{1})}{dz_{1}^{3}} - E_{2}A_{2}\frac{du_{2}(0)}{dx_{2}} = 0,$$

$$-E_{1}I_{1}\frac{d^{2}u_{1}(L_{1})}{dz_{1}^{2}} - E_{2}I_{2}\frac{d^{2}w_{2}(0)}{dx_{2}^{2}} = 0.$$
(2.7)

The reflective symmetric boundary conditions at  $\mathbf{d}$  are

$$u_2(L) = 0, \ \frac{dw_2(L)}{dx_2} = 0, \ -E_2 I_2 \frac{d^3 w_2(L)}{dx_2^3} = F,$$
 (2.8)

where F is the vertical point force applied at **d**. The fixed boundary conditions at **f** are given by

$$u_3(L) = 0, w_3(L) = 0, \frac{dw_3(L)}{dx_3} = 0.$$
 (2.9)

In total, there are 6 differential equations (2.4) and 18 boundary conditions (2.5)-

#### (2.9). The solutions of Eqs. (2.5) are

$$w_{i}(x) = a_{3i}x^{3} + a_{2i}x^{2} + a_{1i}x + a_{0i}, \ i = 2, 3,$$
  

$$u_{1}(z) = b_{31}z^{3} + b_{21}z^{2} + b_{11}z + b_{01},$$
  

$$u_{i}(x) = b_{1i}x + b_{0i}, \ i = 2, 3,$$
  

$$w_{1}(z) = a_{11}z + a_{01}.$$
  
(2.10)

The 18 unknown coefficients  $a_{ij}$ ,  $b_{ij}$  are solved analytically using the 18 boundary conditions using MAPLE.

#### 2.6 Results and Discussion

To validate the model, we compare the theoretically predicted displacement and blocking force with the experimental results. The parameters are shown in Table 2.1. The displacement of the uniflex actuator at **d** is obtained with F = 0 and V = 10 V. The blocking force is obtained by enforcing a clamped boundary condition at **d**, applying V = 10 V, and calculating the vertical resultant force at **d**. The model can also produce the displacement of the unimorph without the cap by setting  $t_a = 0$ .

#### **2.6.1** Rigid Joint Model ( $K_t = \infty$ )

To better understand the physics of the uniflex actuator, we investigate the displacement as a function of a critical parameter in the structural design: The clearance or gap be-

Table 2.1. Parameters for uniflex actuator

Description	
Young's modulus of $Si_x N_y$ , $E_b$ (GPa) [72]	250
Young's modulus of PZT, $E_p$ (GPa) [73]	100
Young's modulus of Al, $E_a$ (GPa) [74]	70
Thickness of $Si_x N_y$ , $t_b$ (µm)	1
Thickness of PZT, $t_p$ ( $\mu$ m)	1, 1.4
Thickness of Al, $t_a$ ( $\mu$ m)	1, 2
Width of actuator, b ( $\mu$ m)	70
Piezo-electric coefficient, $d_{31}$ (C/N) [75]	-40e-12
Permittivity of PZT, $\varepsilon_{33}$ ( $C^2/(Nm^2)$ ) [76]	7.97e-09
Applied potential difference, $V(V)$	10

tween the unimorph and cap,  $L_1$ . In this analysis, Fig. 2.10 shows the theoretical uniflex actuator displacement with  $K_t = \infty$  at the center  $(w_2(L))$  and at the end  $(w_3(0))$  of the uniflex actuator for a 300  $\mu$ m long actuator. For the rigid joint case, sanity checks are made by comparing the predicted uniflex actuator deflections, using our analytical solution, with ANSYS simulations and they are found to agree well with each other. For small clearances, the displacement at the end is actually larger than the displacement at the center. This means that the flexural effect is being overwhelmed by the clamped boundary condition at  $x_2 = 0$ . The clamped boundary condition forces the Al cap downward because the downward slope of the Al cap approximately matches the upward slope of the unimorph if the clearance is small.

In fact, for zero clearance, the cap bends down with the same shape that the unimorph bends up, resulting in zero displacement at center of aluminum cap. As clearance increases  $w_2(L)$  gradually increases due to relaxation obtained from beam 1 deformation. At a critical gap ( $L_1 = 1.6 \ \mu$ m for this set of parameters) the model predicts that the aluminum cap takes a horizontally flat shape after deformation because the boundary rotation causes the same amount of downward deflection as the flexural effect causes upward deflection. Clearly, this is the minimum clearance that is required to ensure that the uniflex actuator produces a maximum displacement  $w_2(L)$  at the center of aluminum cap instead of at the tip of unimorph, thereby, taking advantage of both the unimorph and flexural displacement amplifying mechanisms.

If we make the aluminum cap thickness  $t_a = 0$ , the model can predict the unimorph alone tip displacement  $w_3(0)$  without the aluminum cap. Further, if  $E_b = E_p$ ,  $t_b = t_p = t/2$ , the unimorph tip displacement reduces to

$$w_{3}(0) = \frac{12\varepsilon_{33}L^{2}d_{31}V}{t^{2}\left(8\varepsilon_{33} + E_{p}d_{31}^{2}\right)},$$
(2.11)

where, *t*=total unimorph thickness. As  $E_p d_{31}^2$  is 3 orders smaller than  $\varepsilon_{33}$ , the displacement can be further simplified by neglecting it as

$$w_3(0) = \frac{3L^2 d_{31} V}{2t^2}, \qquad (2.12)$$

which is same as developed by earlier researchers [27] for unimorph actuators. So the model can be used to predict unimorph alone actuator displacement by making aluminum cap thickness as zero.

For the uniflex actuator however, the theoretically predicted displacements under the

assumption of  $K_t = \infty$  are significantly lower than the experimentally measured values. Similar under prediction for the blocking force has also been observed with this model. We hypothesize that this disagreement between theory and experiment arises due to mismatch between the ideal boundary conditions used in the model and the actual boundary conditions that exist in the fabricated actuators that lead to larger displacements. Weakening of the joint b is one possible imperfection that could be caused by poor adhesion between the Al cap and the substrate. For the observed deflections, the expected change in the angle of this joint is ~ 0.8 to 1.8 degree for lengths of actuators from 200  $\mu$ m to 500  $\mu$ m, therefore any imperfections between the interface of the PZT/Al cap layer can easily have the effect of softening this spring. The stress is relatively high at joint b and repeated actuation could also weaken the joint. This weakening would result in less clockwise rotation of beam 1 in the model and a corresponding increase in displacement. The limiting case of such a joint approximates a hinge in which case  $K_t = 0$ 

#### **2.6.2** Weakened Joint Model ( $K_t < \infty$ )

Stiffness  $K_t < \infty$  is introduced into the mathematical model to simulate the uniflex actuators with a weakened joint. Figure 2.11 shows the experimentally measured deflection and the model fitting to the data for the four actuator configurations. In each case the stiffness of the torsional spring  $K_t$  was adjusted to match the experimentally observed data. Figure 2.11 shows that one value of  $K_t$  can be used to match the averaged displacement of several actuators with four different lengths. It must be noted that although



**Figure 2.10.** Geometrically exact uniflex actuator model displacement versus clearance  $L_1$  for an actuator length  $L_a=300 \ \mu\text{m}$ , rigid joint ( $K_t = \infty$ ), Aluminum cap thickness  $t_a = 1 \ \mu\text{m}$ , PZT thickness  $t_p = 1 \ \mu\text{m}$ , and other actuator parameters shown in Tab. 2.1:  $w_2(L)$  (solid line) and  $w_3(0)$  (dashed).

we use  $K_t = \infty$  in the rigid joint approximation, for the devices discussed in this work  $K_t = 1 \ \mu$ Nm/rad already has the effect of an infinitely rigid joint. In comparison to this value the weakened joint model is found use a value of  $K_t$  between 0 - 33 nNm/rad. Furthermore, it is interesting to note that a single value of  $K_t$  seems to fit the observed deflection for all four lengths of the devices tested. However different  $K_t$  values are required for the different stack thickness configurations of the actuators. Since actuators of different lengths but same stack configuration are made under identical fabrication steps it seems reasonable to attribute the origin of weakening of the joint to the fabrication, material, and interface properties between the Al cap and the PZT layers. Since no interface evaluation studies were performed, it is not possible to attribute this effect with any further specificity in terms of process step and/or materials. In addition to the

inclusion of  $K_t$ , the structure of the fabricated device has two other imperfections that need to be mentioned here. The first relates to the built-in stress gradients in the actuator structure which results in a pre-deflected initial state. Typically this initial deflection was less than 5  $\mu$ m for the 500  $\mu$ m long actuators. This worst case initial deflection is relatively small giving a radius of curvature of ~6.25 mm and was therefore not considered as part of the initial modeling. Another imperfection which was not considered arises from the undesired double clamped bridge actuator structure to which the actuator is attached. Since the application of voltage is also expected to actuate this bridge structure, the overall deflection can be expected to be affected by this effect. To reduce this effect, in the design of the actuator, we have minimized the width of electrode that runs on this double clamped structure. Furthermore, any undesired actuation of the PZT double-clamped bridge is likely to induce overall tensile stress in the structure and will essentially pull the bridge structure taut approximating more of the ideal boundary condition. Since all deflections measured were relative to the bridge, we did not consider non-idealities arising from this effect in our model.

The blocking force measurements performed using the nanoindenter were much more complex experiments and the performance of the actuators under these boundary conditions is less well understood. As can be seen in Table 2.2 the experimental blocking force data is far more scattered and shows little patterns of correlation between the geometric dimensions of the actuators and the measured blocking force. In Table 2.2, the blocking force predicted using the developed model is also listed. In each case we



**Figure 2.11.** Displacement versus actuator length  $L_a$  for the four configurations of the actuator: Uniflex experimental data is shown as dots, and theoretical weakened joint displacement  $w_2(L)$  is shown as the solid lines. The individually tuned torsional spring constants that were required to closely match the experimentally observed data are indicated in the figure legend.

used the same torsional spring constant as used for predicting the deflection of the actuators. For the 2  $\mu$ m thick Al cap devices, the agreement between the model and the measured values is close. For other cases the agreement is not so close, but ~50 % of the experimentally observed blocking force. The data from Table 2.2 clearly provides only further evidence of joint weakening in the fabricated uniflex actuators. The scatter in the blocking force data could easily be arising out of the initial loading force of 1.5  $\mu$ N that is used for determining the zero position of the aluminum flexure of the actuator by the nanoindenter. This is a significant proportion of the predicted blocking force of the actuators. This force might cause the double clamped bridge structure which supports the actuator to bend downwards resulting in a perturbed zero position of the actuator. Upon actuation, the tensile stress that will be generated in the bridge structure is likely

Actuator Thickness	Actuator Length	Measured Blocking	Predicted Blocking
(PZT/Al Cap)	(µm)	Force $(\mu N)$	Force $(\mu N)$
1 μm /1 μm	300	16	5.5835
	400	12	3.3718
1 μm /2 μm	300	18.52	20.773
	500	6.2	10.571
1.4 μm /1 μm	300	20.26	8.6304
	500	9.9	4.7568
1.4 μm /2 μm	300	20.4	23.519
	400	17.2	17.005

Table 2.2. Uniflex actuator blocking force experimental data and theoretical predictions

**Table 2.3.** Uniflex<sup>\*</sup> actuator displacement amplification over unimorph actuator for PZT thickness  $t_p = 1.4 \ \mu\text{m}$ , Si<sub>3</sub>N<sub>4</sub> thickness  $t_b = 1 \ \mu\text{m}$ , and Aluminum thickness<sup>\*</sup>  $t_a = 1 \ \mu\text{m}$  at 10 V

Actuator Length	Unimorph Displacement	Uniflex Displacement	Amplification
$(L_a)$ ( $\mu$ m)	$(w_3(0)) (\mu m)$	$(w_2(L)) (\mu m)$	$(\frac{w_2(L)}{w_3(0)})$
300	2.38	3.48	1.46
400	3.61	5.06	1.40
500	5.17	7.45	1.44

to cause it to flatten, essentially resulting in additional blocking force to be added to the measurement. This can easily result in the observed scatter in the experimental results. On the other hand, deflection measurements performed under zero loading force do not suffer from this situation and show less scatter.

Overall the uniflex actuators presented show a performance that is superior to reports in the literature on similar unimorph actuators. While a direct comparison without accounting for the detailed geometric, structural, and material factors makes it difficult, cantilever type unimorph actuators have been reported to obtain blocking forces in the range of 2 - 55  $\mu$ N with a maximum deflection of 6 - 1  $\mu$ m at drive voltages of 2 - 10 V

respectively [77, 78]. The values of deflection and blocking force reported in this work for the 1.4  $\mu$ m thick PZT and 1 and 2  $\mu$ m thick Al cap, clearly exhibit higher values than these reported values. In this work, as shown in table 2.3, we were able to obtain ~40% greater deflection in the uniflex actuators (1  $\mu$ m thick Aluminum cap) as compared to the similar unimorph actuators proving the efficacy of the uniflex design.



# Optimization of Piezoelectric Uniflex Actuator

## 3.1 Introduction

In this chapter, we optimize and compare the performance of a uniflex actuator with unimorph and flextensional actuators in terms of displacement and blocking force. The uniflex model developed and validated in Chapter 2 is used to predict displacement and blocking force.

# 3.2 Unimorph, Flextensional, and Uniflex Actuators

Fig. 3.1(a) shows the schematic of a deflected unimorph actuator. The passive bottom layer is assumed to be  $Si_xN_y$  and the top layer PbZr<sub>0.52</sub>Ti<sub>0.48</sub>O<sub>3</sub> (PZT). Electrodes are



**Figure 3.1.** Schematic of deflected (a) unimorph, (b) flextensional, and (c) uniflex actuators. placed on the top and bottom of the PZT layer. The PZT is poled through the thickness and voltage applied across the thickness causes the PZT layer to contract due to the  $d_{31}$ coeffcient, resulting in upward bending of the actuator. The flextensional actuator shown in Fig. 3.1(b) uses the flexural motion of an aluminum (Al) cap to produce displacement. Voltage applied across the thickness of the bulk PZT contracts the PZT and flexes the Al cap upward.

The uniflex actuator shown in Fig. 3.1(c) consists of a unimorph that is supported at the center and an Al cap that is bonded at the ends of the unimorph. The Al cap is bonded to the ends of unimorph structure such that there is a small offset from PZT. As in the unimorph, the PZT is poled through the thickness and electroded on both top and bottom. Voltage across the thickness causes PZT contraction and bending of the unimorph. The Al cap is compressed by the unimorph and, if correctly designed, buckles upward. Thus, the uniflex actuator combines the unimorph and flexural displacement amplification mechanisms to produce large vertical displacement at the center of the Al cap.

### **3.3** Mathematical Models

Mathematical models for displacement and blocking force of a uniflex actuator are developed and validated [79, 68]. The free displacement of a uniflex actuator at the center of aluminum cap is

$$w_{UF} = \frac{C_1 L^3 + C_2 L^2}{C_3 L^2 + C_4 L + C_5},$$
(3.1)

where *L* is the half length of the actuator and the coefficients  $C_1,...,C_5$  are defined in Appendix A and depend on the system parameters:  $E_a$ ,  $E_b$ , and  $E_p$  are the Young's moduli,  $t_a$ ,  $t_b$ , and  $t_p$  are the thicknesses,  $A_a$ ,  $A_b$ , and  $A_p$  are the cross-sectional areas,  $I_a$ ,  $I_{be}$ , and  $I_{pe}$  are moments of inertia about the neutral axis of aluminum cap, silicon nitride, and PZT respectively, and  $L_1$  is the initial gap between Al cap and PZT. The parameters  $a_2$ ,  $a_3$ ,  $a_4$ , and  $a_8$  are the electromechanical factors,  $\delta$  is the offset, and  $K_t$  is the joint stiffness.

The blocking force of a uniflex actuator, defined as the force required to constrain the center of aluminum cap at zero vertical displacement upon actuation is

$$F_{UF} = 2w_{UF} \left( \frac{-B_7 L^2 - B_8 L - B_9}{B_1 L^5 + B_2 L^4 + B_3 L^3 + B_4 L^2 + B_5 L + B_6} \right),$$
(3.2)

where the coefficients  $B_1,...,B_9$  are defined in Appendix A.

The displacement  $w_F$  and blocking force  $F_F$  of flextensional actuator at the center of the aluminum cap are obtained directly from equations 3.1 and 3.2 by equating the thickness of silicon nitride layer  $t_b$  to zero.

For the unimorph (shown in Fig. 3.1(a)), the displacement  $w_U$  and blocking force  $F_U$  are evaluated at the tip. The tip displacement  $w_U$ , obtained by letting aluminum cap thickness  $t_a = 0$  in the uniflex model [79], is

$$w_U = \frac{L^2 a_4 A_p}{2 \left( E_b I_{be} + 2a_2 I_{pe} + 2a_3 A_p \right)} , \qquad (3.3)$$

and the blocking force is

$$F_U = \frac{3a_4 A_p}{L}.\tag{3.4}$$



**Figure 3.2.** Maximum displacement versus actuator length: uniflex actuator  $w_{UF}$  with  $t_a = 1 \ \mu m$  (solid), unimorph actuator  $w_U$  (dotted), and flextensional actuator  $w_F$  with  $t_a = 1 \ \mu m$  (dashed).



**Figure 3.3.** Blocking force for maximum displacement design versus actuator length: uniflex actuator  $F_{UF}$  with  $t_a = 1 \ \mu m$  (solid), unimorph actuator  $F_U$  (dotted), and flextensional actuator  $F_F$  with  $t_a = 1 \ \mu m$  (dashed).

#### **3.4 Optimal Design**

The uniflex model predicts the displacement and blocking force of uniflex actuators, so it can be used to optimize the uniflex design. The uniflex design has many geometric parameters that can be optimized:  $L_a$ , b,  $L_1$ ,  $t_a$ ,  $t_p$ , and  $t_b$ . The actuator length includes the active and a 40  $\mu$ m bonding region so  $L_a = 2L + 40 \mu$ m. The displacement and blocking force increase and decrease with actuator length  $L_a$ , respectively, so it is considered to be an input to the design. The actuator width, b, does not affect displacement and proportionally scales blocking force, so it is held constant at 70  $\mu$ m. The material properties given in Tab. 2.1 with  $d_{31} = -30$  pC/N,  $K_t = 4e - 9$  are used. A constant electric field of 20 V/ $\mu$ m is applied for all the actuators during comparison. The overall thickness of the unimorph is held constant at  $t_p + t_b = 2 \mu$ m.

The optimal uniflex results are compared with an optimal 2  $\mu$ m thick unimorph of length 2*L* and an optimal flextensional actuator of length *L<sub>a</sub>*. Optimization is performed by the pattern search algorithm in MATLAB.

The unimorph has an optimal ratio  $t_p/t_b = 1.58$  that produces both maximum displacement and blocking force. The flextensional actuator is the same as uniflex actuator except that  $t_p = 0$ . The clearance  $L_1$  and thickness  $t_a$  are optimized as in the uniflex actuator to produce maximum displacement or maximum blocking force.

In the following, we optimize  $L_1$ ,  $t_p/t_b$  and  $t_a$  to either produce maximum displacement or blocking force for uniflex actuators. The optimal uniflex designs are compared with the optimal unimorph and flextensional actuators.



**Figure 3.4.** Maximum displacement versus Al thickness ( $L_a = 300 \ \mu$ m): uniflex  $w_{UF}$  (solid), unimorph  $w_U$  (dotted), and flextensional  $w_F$ (dashed).



**Figure 3.5.** Blocking force for maximum displacement design versus Al thickness ( $L_a = 300 \ \mu$ m): uniflex  $F_{UF}$  (solid), unimorph  $F_U$  (dotted), and flextensional  $F_F$  (dashed).



Figure 3.6. Clearance for maximum displacement design versus Al thickness ( $L_a = 300 \ \mu$ m): uniflex (solid) and flextensional (dashed).

#### 3.4.1 Maximized Displacement Design

Optimization of the flextensional and uniflex designs for maximum displacement with all the parameters  $L_1$ ,  $t_p/t_b$  and  $t_a$  as variables for a given actuator length  $L_a$  produces a thin aluminum cap, with  $t_a$  approaching zero. We therefore first fix  $t_a$ , and find the ratio  $t_p/t_b$  and clearance  $L_1$  that maximize actuator displacement. For optimization using the pattern search algorithm, the objective function is to maximize displacement with constraints  $t_a = 1 \ \mu m$ ,  $t_p/t_b = 0$  to 1,  $L_1 = 0$  to  $\infty$  and actuator length  $L_a$  prescribed from 200 to 500  $\mu m$  in increments of 10  $\mu m$ .

Figures 3.2 and 3.3 show the displacement and corresponding blocking force for

actuators that are designed to maximize displacement. The displacement of all three actuators increases with the actuator length. The uniflex actuator maximum displacement in Fig. 3.2 is higher than that of the optimal unimorph and flextensional actuators. The optimal clearance  $L_a/L_1 \approx 300$  and the optimal  $t_p/t_b \approx 2$  for the displacement optimized uniflex actuator with  $t_a = 1 \ \mu m$  and 200  $\mu m < L_a < 500 \ \mu m$ . The blocking force in Fig. 3.3, however, is lower than the unimorph but higher than the flextensional actuator.

Inorder to study the effect of aluminum cap thickness  $t_a$  on maximum displacement , we fix the actuator length  $L_a = 300 \ \mu\text{m}$  and find optimum clearance  $L_1$  and ratio  $t_p/t_b$ that produces maximum displacement for a given  $t_a = 0.4$  to 5  $\mu$ m. Figures 3.4 and 3.5 show the displacement and blocking force variations with  $t_a$  for the displacement optimized actuators. The unimorph actuator has no Al cap, so the displacement and blocking force are independent of  $t_a$  at the values for  $L_a = 300 \ \mu\text{m}$  of  $w_U(0) = 3.8 \ \mu\text{m}$  and  $F_U = 73 \ \mu\text{N}$ . The flextensional effect is amplified at low  $t_a$  for both the uniflex and flextensional designs showing that the optimal aluminum cap thickness  $t_a$  is the thinnest physically possible layer. The unimorph blocking force, however, is greater than the uniflex and flextensional designs, which vanishingly small as  $t_a \rightarrow 0$ . As  $t_a$  gets large, the uniflex displacement and blocking force converge to the unimorph values from above and below, respectively. The optimal clearance (see Fig. 3.6) is more sensitive to  $t_a$ , increasing from  $L_a/L_1 = 300$  to 5.4 as  $t_a = 1 \ \mu\text{m}$  to 5  $\mu\text{m}$ . The optimal ratio  $t_p/t_b$  is found to decrease from 2.1 to 1.6 over this range of  $t_a$ .



**Figure 3.7.** Maximum blocking force versus actuator length: uniflex actuator  $F_{UF}$  with clearance  $L_1 = 2.7 \ \mu \text{m}$  (solid), unimorph actuator  $F_U$  (dotted), and flextensional actuator  $F_F$  with clearance  $L_1 = 2.7 \ \mu \text{m}$  (dashed).



**Figure 3.8.** Displacement for maximum blocking force design versus actuator length: uniflex actuator  $w_{UF}$  with clearance  $L_1 = 2.7 \ \mu m$  (solid), unimorph actuator  $w_U$  (dotted), and flextensional actuator  $w_F$  with clearance  $L_1 = 2.7 \ \mu m$  (dashed).



**Figure 3.9.** Maximum blocking force versus clearance ( $L_a = 300 \ \mu$ m): uniflex actuator  $F_{UF}$  (solid), unimorph  $F_U$  (dotted), and flextensional actuator  $F_F$  (dashed).

#### 3.4.2 Maximized Blocking Force Design

Similar to the maximum displacement design, optimization of the uniflex actuator for maximum blocking force with all the parameters as variables for a given actuator length  $L_a$  increases the clearance  $L_1$  to excessively large values. We therefore first fix  $L_1 = 2.7 \ \mu$ m and find the  $t_p/t_b$  ratio and aluminum cap thickness  $t_a$  for a given actuator length  $L_a$  that maximize the blocking force. Figures 3.7 and 3.8 show the optimization results for the maximized blocking force designs versus  $L_a$ . The blocking force (Fig. 3.7) decreases with increasing actuator length for all three actuators. The uniflex blocking force is larger than the displacement optimized designs in Fig. 3.8 increases with actuator length. The uniflex displacement is smaller than the displacement-optimized designs in Fig. 3.2.



**Figure 3.10.** Displacement for maximum blocking force design versus clearance ( $L_a = 300 \,\mu$ m): uniflex actuator  $w_{UF}$  (solid), unimorph  $w_U$  (dotted) and flextensional actuator  $w_F$  (dashed).

The unimorph actuator produces the highest blocking force followed by the uniflex and flextensional actuators. The uniflex and unimorph actuators produce similar displacement with the flextensional design producing significantly less displacement. From the optimization it is found that with the increasing actuator length ( $L_a$ ), the optimum aluminum cap thickness ( $t_a$ ) and ratio ( $t_p/t_b$ ) remain approximately constant ( $t_a \approx 2.2 \ \mu m$  and  $t_p/t_b \approx 1.65$ ) for the uniflex actuator with  $L_1 = 2.7 \ \mu m$ .

Now the effect of clearance  $L_1$  is studied for a fixed actuator length  $L_a = 300 \ \mu \text{m}$ by varying the ratio  $t_p/t_b$  and aluminum cap thickness  $t_a$  for a given clearance  $L_1 = 0$  to 40  $\mu$ m producing maximum blocking force. Figures 3.9 and 3.10 show the maximized blocking force design versus clearance. In Fig. 3.8, the uniflex maximum blocking force increases monotonically and approaches the unimorph. The flextensional blocking



**Figure 3.11.** Aluminum cap thickness  $t_a$  for maximum blocking force design versus clearance  $(L_a = 300 \ \mu\text{m})$ : uniflex actuator (solid) and flextensional actuator (dashed).

force, on the other hand, increases initially and then decreases for  $L_1 > 3 \ \mu$ m. The corresponding displacements (Fig. 3.10) remain almost constant and approach zero for the uniflex and flextensional actuators, respectively, as  $L_1$  increases. The uniflex and flextensional designs have a thicker aluminum cap as  $(L_1)$  increases as shown in Fig. 3.11. The uniflex actuator optimum  $t_p/t_b \approx 1.65$  for these cases.

The optimization results show that a properly designed uniflex actuator produces more displacement than the unimorph and flextensional actuators. With a thick cap and large gap the uniflex actuator approaches but does not exceed the unimorph blocking force.



# **Piezoelectric T-beam Actuators**

### 4.1 Introduction

This chapter introduces a novel monolithic T-beam actuator design that can be fabricated from bulk PZT by dicing or micro-machining and does not require bonding of two layers. This chapter describes the design, fabrication, and testing of meso-scale prototypes that are diced from bulk PZT. Although micro-scale T-beam actuators are not described here, they can be fabricated using Reactive Ion Etching [69] and the models developed in this thesis can be applied to their design and optimization. The meso-scale T-beam actuators fabricated are experimentally shown to produce both out-of-plane and in-plane displacements and out-of-plane blocking force. Models are developed that predict inplane and out-of-plane displacement and out-of-plane blocking force as functions of the T-beam parameters and the applied voltage. Experimental measurements of displacements and blocking forces validate the theoretical models. Model-based analysis and



**Figure 4.1.** T-beam actuator concept: (a) As fabricated and deflected shapes when voltage is applied between (b) both flanges and bottom electrodes, (c) web and bottom electrode, (d) left flange and bottom electrode, and (e) right flange and bottom electrode.

optimization are used to optimize the T-beam actuator geometry to produce large displacement and blocking force. T-Beam out-of-plane displacement and blocking force performance is compared with a unimorph.

#### 4.2 The T-Beam Actuator Concept

The schematic design of a cantilevered T-beam actuator that has a T-shaped crosssection is shown in Fig. 4.1. The entire T-beam is PZT with electrodes deposited on the top of the web, the top of each flange, and the bottom of the flange. The PZT is poled through-the-thickness from top to bottom.

Fig. 4.1 shows that the T-beam actuator can be bent both in-plane and out-of-plane by selectively activating the various electrodes. The bottom electrode acts as a ground. Out-of-plane motion can be achieved by applying voltage to the web electrode or to both flange electrodes. Application of voltage to the web electrode causes the web to expand through the thickness and contracts ( $d_{31}$  piezoelectric effect). The inactive flange constrains the lower part of the T-beam, acting as the passive layer in a unimorph design, and the beam bends upward (see Fig. 4.1(b)). Alternatively, the two flanges contract due to flange actuation, the web resists contraction, and the T-beam bends downward (see Fig. 4.1(c)).

The T-beam can also provide in-plane displacement by differential application of voltage to the two flanges. For in-plane bending the left and right flange electrodes are actuated to produce left and right bending as shown in Figs. 4.1(d) and 4.1(e), respectively.

Preliminary investigations of T-beams are performed using the finite element models. ANSYS SOLID5 three dimensional piezoelectric coupled field elements are used to model the entire T-beam. Cantilevered boundary conditions are applied with dis-



**Figure 4.2.** Web actuated cantilevered T-beam: (a) Transverse deflection, and (b) electric field placements rigidly fixed at left end and left free at right end. Figure 4.2(a) shows the transverse deflection of the T-beam for web actuation when voltage is applied between top of the web and entire bottom electrode region. Figure 4.2(b) shows that the electric field is concentrated in the web region under web actuation. Similarly, electric field is concentrated in the flange region under flange actuation and in the single flange under single flange actuation.

#### 4.3 Analytical Modeling

To understand the physical behavior of the T-beam actuator and optimize its performance we develop a physics based model that predicts its out-of-plane and in-plane displacement and blocking force. The T-beam actuator with the web and flange electrodes shown in Fig. 4.3 is modeled as a cantilever beam using Euler-Bernoulli beam theory and assuming uniform electric field through the thickness. Fig. 4.3(a) shows a schematic of the initial and deflected shapes of the T-beam actuator in both out-of-plane (top) and in-plane (bottom) directions. The beam is assumed to be initially straight and lying along the longitudinal x1 axis.  $F_2$  and  $F_3$  are the horizontal (inplane) and vertical



**Figure 4.3.** T-beam model: (a) the initial and deflected shape (out-of-plane (top) and in-plane (bottom)) and (b) cross section.

loads passing through the shear center of beam such that they do not cause twist. The variables u, v and w denote the displacements in the longitudinal  $(x_1)$ , transverse inplane  $(x_2)$  and transverse out-of-plane  $(x_3)$  directions, respectively. The cross-section of the T-beam shown in Fig. 4.3(b) has a flange width s, flange thickness t, web thickness b, and overall height h. The longitudinal axis runs through the centroid of the T-beam cross section, halfway through the cross section in the x3 direction and through the centroidal at a distance

$$e = \frac{1}{2} \frac{t^2 s - t^2 b + 2tbh - bh^2}{ts - tb + bh},$$
(4.1)

below the top of the flange. As shown in Fig. 4.3 (b), the bottom electroded is subdivided into three regions under the right and left flanges and the web. For upward out-of-

plane actuation, voltage, V is applied between the web and the middle electrode on the bottom of the flange. Voltage applied between right or left flange electrodes and the corresponding outer electrode on the bottom of the flange produces in-plane motion. We assume uniform and constant electric field along the  $x_3$  axis through the thickness of actuator as shown in Fig. 4.3(b). For flange actuation,  $V = \phi_{flange} - \phi_{bottom}$  and we neglect the field in the web. For web actuation  $V = \phi_{web} - \phi_{bottom}$  and we neglect the field in the flanges.

The governing equations are obtained using the principle of virtual work. The potential energy of the T-beam actuator is

$$U_{b} = \int_{V_{b}} \frac{E}{2} \left( u' - x_{2}v'' - x_{3}w'' \right)^{2} dV,$$

$$U_{p} = \int_{V_{p}} H dV, U = U_{b} + U_{p},$$
(4.2)

where  $()' = \frac{d()}{dx_1}$ , *E* is the Young's modulus of PZT,  $U_b$  and  $U_p$  are the potential energy of the passive region and active region, respectively, and *U* is the total potential energy.

The electric enthalpy *H* for the active piezoelectric material, obtained from piezoelectric constitutive equations [69, 32] and electric boundary conditions  $V = \phi_{web} - \phi_{bottom}$  and  $V = \phi_{flange} - \phi_{bottom}$  for web and flange actuations, respectively, is given by

$$H = \frac{E}{2} (u'')^{2} + \frac{E}{2} x_{2}^{2} (v'')^{2} - E x_{2} u' v'' + (a_{2} x_{3}^{2} + a_{3}) (w'')^{2} + a_{4} V w'' + a_{5} V^{2} + (a_{6} + a_{7} x_{3}) w'' u' - (a_{7} x_{2} x_{3} + a_{6} x_{2}) w'' v''$$

$$+ a_{8} V u' - a_{8} V x_{2} v'',$$
(4.3)

Coefficient	Web	Flange
<i>a</i> <sub>2</sub>	$\frac{1}{2}\left(E+\frac{e_{31}^2}{\varepsilon_{33}}\right)$	$\frac{1}{2}\left(E+\frac{e_{31}^2}{\varepsilon_{33}}\right)$
<i>a</i> <sub>3</sub>	$-\frac{e_{31}^2(2e+h-2t)^2}{8\varepsilon_{33}}$	$-\frac{e_{31}^2(2e-t)^2}{8\epsilon_{33}}$
$a_4$	$-\frac{e_{31}\left(2e+h-2t\right)}{2h}$	$-\frac{e_{31}(2e-t)}{2t}$
$a_5$	$\frac{-\epsilon_{33}}{2h^2}$	$\frac{-\varepsilon_{33}}{2t^2}$
$a_6$	$\frac{e_{31}^2}{2\varepsilon_{33}}(2e+h-2t)$	$\frac{e_{31}^2}{2\varepsilon_{33}}(2e-t)$
<i>a</i> <sub>7</sub>	$-\frac{E\varepsilon_{33}+e_{31}^2}{\varepsilon_{33}}$	$-\frac{E\varepsilon_{33}+e_{31}^2}{\varepsilon_{33}}$
$a_8$	$\frac{e_{31}}{2h}$	$\frac{e_{31}}{2t}$

Table 4.1. Electromechanical coefficients for web and flange actuation

where  $e_{31} = Ed_{31}$  is piezo-electric stress coefficient, and  $\varepsilon_{33} = K_{33}\varepsilon_0$  is the permittivity of PZT [32]. The coefficients in Eq. (4.3) are given in Table 4.1 for web and both flange actuation and  $d_{31}$  is the piezoelectric strain coefficient, *K* is relative permittivity of PZT, and  $\varepsilon_0$  is the permittivity of free space.

Substitution of Eqs. (4.2) into the principal of virtual work,  $\int_{0}^{t} (\delta U + F_2 \delta v(L) + F_3 \delta w(L)) dt = 0$ , produces the field equations

$$\frac{d^4w(x_1)}{dx_1^4} = 0, \frac{d^4v(x_1)}{dx_1^4} = 0, \frac{d^2u(x_1)}{dx_1^2} = 0, \forall x \in (0,L),$$
(4.4)

geometric boundary conditions at the fixed end

$$u(0) = 0, v(0) = 0, w(0) = 0, \frac{dv(0)}{dx} = 0, \frac{dw(0)}{dx} = 0,$$
(4.5)

and the natural boundary conditions at the free end

$$E (A_b + A_p) \frac{du(L)}{dx} + a_8 A_p V = 0,$$
  

$$E (I_{p2} + I_{b2}) \frac{d^2 v(L)}{dx_1^2} - a_8 A_{p2} V = 0,$$
  

$$E (I_{p2} + I_{b2}) \frac{d^3 v(L)}{dx_1^3} - F_2 = 0,$$
  

$$(EI_{b3} + 2a_2 I_{p3} + 2a_3 A_p) \frac{d^3 w(L)}{dx_1^3} - F_3 = 0,$$
  

$$(EI_{b3} + 2a_2 I_{p3} + 2a_3 A_p) \frac{d^2 w(L)}{dx_1^3} + a_4 A_p V = 0,$$
  
(4.6)

where  $(A_p, A_b)$ ,  $(A_{p2}, A_{b2})$ ,  $(I_{p2}, I_{b2})$ , and  $(I_{p3}, I_{b3})$  are the cross-sectional area, first moment of area, and second moment of area of the active and passive regions, respectively, about the neutral axis as given in Tab. 4.2.

The solutions of Eqs. (4.4) are

$$u(x_1) = b_1 x_1 + b_0,$$
  

$$v(x_1) = c_3 x_1^3 + c_2 x_1^2 + c_1 x_1 + c_0.$$
  

$$w(x_1) = d_3 x_1^3 + d_2 x_1^2 + d_1 x_1 + d_0.$$
  
(4.7)

The 10 unknown coefficients  $b_j$ ,  $c_i$ ,  $d_i$  are solved analytically using the 10 boundary

Constant	Web	Flange	Single flange
$A_b$	t(s-b)	bh	$\frac{(2h-t)b+st}{2}$
$A_p$	bh	t(s-b)	$\frac{(s-b)t}{2}$
$A_{p2}$	0	0	$\frac{t\left(s^2-b^2\right)}{8}$
$I_{b2}$	$\frac{t}{12}\left(s^3-b^3\right)$	$\frac{b^3h}{12}$	$\frac{(2h-t)b^3+s^3t}{24}$
$I_{p2}$	$\frac{b^3h}{12}$	$\frac{t}{12}\left(s^3-b^3\right)$	$\frac{t\left(s^3-b^3\right)}{24}$
I <sub>b3</sub>	$\frac{(s-b)t^3}{12} + A_b \left(e - \frac{t}{2}\right)^2$	$\frac{bh^3}{12} + A_b \left(e - t + \frac{h}{2}\right)^2$	$I_{p3} + \frac{bh^3}{12} + bh\left(e - t + \frac{h}{2}\right)^2$
<i>I</i> <sub>p3</sub>	$\frac{bh^3}{12} + A_p \left(e - t + \frac{h}{2}\right)^2$	$\frac{(s-b)t^3}{12} + A_p \left(e - \frac{t}{2}\right)^2$	$\frac{(s-b)t^3}{24} + A_p \left(e - \frac{t}{2}\right)^2$

**Table 4.2.** Cross-sectional area, first moment of area, and second moment of area for web, flange and, single flange actuation

conditions to obtain

$$w(x_{1}) = \frac{-(LF_{3} + a_{4}VA_{p})x_{1}^{2}}{2(2a_{2}I_{p3} + 2a_{3}A_{p} + E_{p}I_{b3})} + \frac{F_{3}x_{1}^{3}}{6(2a_{2}I_{p3} + 2a_{3}A_{p} + E_{p}I_{b3})},$$
  

$$v(x_{1}) = \frac{(-LF_{2} + a_{8}VA_{p2})x_{1}^{2}}{2E_{p}(I_{p2} + I_{b2})} + \frac{F_{2}x_{1}^{3}}{6E_{p}(I_{p2} + I_{b2})},$$
(4.8)
The tip displacements obtained by substituting  $x_1 = L$  in Eq. (4.8) are

$$v(L) = -\frac{L^{3}F_{2}}{3E_{p}(I_{p2} + I_{b2})} + \frac{a_{8}A_{p2}L^{2}V}{2E_{p}(I_{p2} + I_{b2})},$$

$$w(L) = -\frac{L^{3}F_{3}}{3(2a_{2}I_{p3} + 2a_{3}A_{p} + E_{p}I_{b3})} - \frac{a_{4}A_{p}L^{2}V}{2(2a_{2}I_{p3} + 2a_{3}A_{p} + E_{p}I_{b3})},$$
(4.9)

The free tip displacements,  $v_f$  and  $w_f$  defined as the displacement at the tip of actuator when the applied force  $F_2$  and  $F_3$  equal to zero. From Eq. (4.9) the expressions for free displacement can be obtained as

$$v_{f} = \frac{a_{8}A_{p2}L^{2}V}{2E_{p}(I_{p2} + I_{b2})},$$

$$w_{f} = -\frac{a_{4}A_{p}L^{2}V}{2(2a_{2}I_{p3} + 2a_{3}A_{p} + E_{p}I_{b3})},$$
(4.10)

are obtained by substituting  $F_2=F_3=0$  in Eq.4.9. The blocking forces,

$$F_{2b} = -\frac{3a_8 A_{p2} V}{2L},$$

$$F_{3b} = \frac{3a_4 A_p V}{2L}$$
(4.11)

constrain the tip displacements v(L)=w(L)=0 in Eq.4.9.

#### 4.3.1 Nondimensional modeling

Two nondimensionalization schemes are used to validate the model and optimize the T-beam performance. For the model validation nondimensionalization, we reduce the parametric model to a simple linear relationship between the nondimensional voltage and the nondimensional displacements and blocking forces. In this way, all of the obtained experimental data can be shown on one plot, regardless of the device parameters. The nondimensional parameters

$$x_1^* = \frac{x_1}{L}, w^* = \frac{w}{L}, v^* = \frac{v}{L},$$
 (4.12)

are introduced into Eq. 4.4 to produce

$$w^{*}(1) = F_{3}^{*} + V_{3}^{*}, v^{*}(1) = F_{2}^{*} + V_{2}^{*},$$
(4.13)

where the nondimensional forces and voltages in the out-of-plane and in-plane directions are

$$F_2^* = -\frac{\kappa}{3\gamma}, F_3^* = -\frac{\beta}{3\alpha}, V_2^* = -\frac{\psi}{2\gamma}, V_3^* = -\frac{\tau}{2\alpha},$$
(4.14)

with the parameters

$$\alpha = 1 + \frac{2a_2I_{p3}}{EI_{b3}} + \frac{2a_3A_p}{EI_{b3}}, \beta = \frac{F_3L^2}{EI_{b3}}, \tau = \frac{a_4VA_pL}{EI_{b3}},$$

$$\gamma = 1 + \frac{I_{p2}}{I_{b2}}, \kappa = \frac{F_2L^2}{EI_{b2}}, \psi = -\frac{a_8VA_{p2}L}{EI_{b2}},$$
(4.15)

From Eq. (4.13) the nondimensional free tip displacements

$$v_f^* = V_2^*, w_f^* = V_3^*, (4.16)$$



**Figure 4.4.** Schematic illustration of T-beam fabrication: (a) start with 1mm thick bulk PZT-4 with Cr/Au coating, (b) dice to form web regions, (c) etch bottom electrodes, (d) spray photoresist pattern and evaporate Cr/Au for flange electrodes, (e) lift-off photoresist to form flange electrodes, (f) release individual T-beams by dicing.

and the non-dimensional blocking forces

$$F_{2b}^* = -V_2^*, \ F_{3b}^* = -V_3^*. \tag{4.17}$$

### 4.4 Fabrication Process

A schematic illustration of the T-beam fabrication process using a precision dicing saw and photolithography is shown in figure 4.4. We start with a 25.4 X 25.4 mm X 1 mm PZT-4 chip with both sides polished and coated with a layer of Cr/Au as shown in figure 4.4(a). The web regions are defined using a K & S Model 980 precision dicing saw (Fig. 4.4(b)). Height calibration ensures  $\pm 10 \,\mu$ m resolution in the vertical direction. A resolution of approximately 20  $\mu$ m is obtained in the horizontal direction. A thick layer of Shipley 1827 photoresist spun using a Model PWM32 Headway Research, Inc spinner at 1000 rpm for 20 seconds and cured at 115C protects the uncut PZT from particles created during dicing and is then removed in acetone and IPA.

High quality, precleaned VWR microscope glass slides function as sample holders for the PZT chip using Shipley 1827 (1000 RPM, 20 seconds, 115 °C for 15 minutes) as mounting adhesive. The PZT is mounted upside down and spin coated with Shipley 1827 (3000 RPM, 40 seconds, 115 °C for 15 minutes). The Karl Suss MJB-3 Contact aligner provides 0.9 mW/cm<sup>2</sup> at 315 nm of exposure and transparency masks drawn in Corel Draw X4 provide sufficient resolution (approximately 50  $\mu$ m) to pattern the bottom electrodes. The large thickness of the photoresist requires a high exposure time (7 minutes) as compared to conventional silicon processes. The chip is developed in 3:1 Microposit<sup>™</sup> 351 developer and DI water for one minute. Gold etchant-Type TFA and Chrome etchant-Type 1020 defines the bottom electrode and a Cole Parmer 8892 ultrasonic bath of acetone unmounts the chip as shown if figure 4.4(c). After cleaning, the chip is remounted right side up and spray coated with Shipley 1805 photoresist (115 °C, 10 minutes) using a Badger Model 250 spray gun. The flange electrode mask is then aligned, patterned, and inspected under a microscope. Significant nonuniformity in the S1805 spray coat and the high aspect ratio of the sample require multiple exposures at very high exposure times (> 14 minutes). A conformal layer of 15 nm Cr and 150 nm Au are evaporated onto the substrate using a planetary sample holder on an electron beam evaporator with a MDC Mighty Source<sup>TM</sup> as shown in figure 4.4(d). An ultrasonic

Device	Length	Total width	Flange thickness	Height	Web width
	$L (\mathrm{mm})$	s (µm)	<i>t</i> (µm)	$h(\mu m)$	<i>b</i> (µm)
1	14.6	2012	134	1000	765
2	20.4	2008	298	1000	774
3	20.1	2000	417	1000	764
4	20.4	1993	612	1000	756
5	21.3	2017	788	1000	770
6	20.7	1995	320	1000	512

 Table 4.3. Fabricated prototype parameters

acetone bath performs the liftoff procedure removing photoresist and gold from the undesired areas as shown in figure 4.4(e). The final T-beams are released by dicing (see figure 4.4(f)).

The T-Beams are then packaged onto custom designed PCBs and wirebonded using a K&S Model 4524 wirebonding machine. Due to high surface roughness of flange H20E EPO-TEK® silver conductive epoxy is used to hold the 25  $\mu$ m gold wirebond to the flange and cured at 115 °C. In total, 6 independent electrodes (3 on top and 3 on bottom) enable actuation of T-beam in both out-of-plane and in-plane directions.

### 4.5 **Prototyping and Experimental Setup**

Six devices are built with the different configurations shown in Table 4.3. Five of the devices have different flange thicknesses and approximately same length and web thickness except for first one which had its tip broken off during fabrication. Figure 4.5 shows the picture of fabricated and mounted Device 4. The inset zooms in on the cross-section



Figure 4.5. Photograph of a fabricated and mounted T-beam (Device 4) actuator.

of T-beam at the tip. The 0.8 mm thick FR4 circuit board is attached along its edges thicker 1.6 mm FR4 base which then is attached to linear stages that allow precise positioning of the actuator. High resolution pictures of cross-section, top-view, and bottom view of each device are used to measure the various geometric parameters with a precision of approximately  $\pm 20 \ \mu$ m in cross-sectional dimensions and  $\pm 50 \ \mu$ m in length. The material properties of PZT-4 used for T-beams are given in table 4.4.

The experimental setup used to measure the displacement and blocking force of the actuators is shown in figure 4.6. A model OFV5000 Polytec laser vibrometer controller with OFV534 sensor head measures the displacement with a measuring spot size of 20  $\mu$ m. A 3-axis Newport linear stage with micrometer screws accurately positions the T-beam so that the laser is precisely focused at the desired location. An Aurora 402A force transducer with a 1 mm diameter glass tube sensing tip is used to measure

the blocking force. The force transducer has a resolution of 10 nN and can measure up to 500 mN. The force transducer is mounted on two Aurora linear stages to allow positioning the sensor tip at the desired location on the T-beam. A model 609E6 Trek amplifier generates the desired voltage running.



**Figure 4.6.** Photograph of experimental set-up to measure displacement and blocking force of T-beam actuators.

 Table 4.4. PZT-4 material properties

Description	
Youngs modulus of PZT, E (GPa)	78
Piezoelectric strain coefficient, $d_{31}$ (C/N)	-122e-12
Permittivity of PZT, $\varepsilon_{33}$ ( $C^2/(Nm^2)$ )	1.15e-08

### 4.6 Experimental Testing and Validation

The six independent electrical connections on the fabricated T-beams enable web, flange, right flange or left flange actuation to produce out-of-plane and in-plane motions. Blocking force measurements are performed only for web and flange actuations due to the difficulty in measuring transverse forces.

A triangle wave signal at 1 Hz frequency (total 10 cycles) actuates the T-beam such that the electric field  $\phi$  is always in the direction of poling. The experiment is repeated for peak electric fields of 0.1, 0.2, 0.3, 0.4, 0.5 V/ $\mu$ m for both displacement and blocking force measurements. The peak voltage applied is  $V = \phi h$  for web actuation and  $V = \phi t$ for flange actuation and the un-actuated electrodes are allowed to float. To account for the compliance of force sensor and FR4 mounting, displacement measurements are taken at the tip and base of the T-beam actuator during blocking force measurements.

Figure 4.7 shows the out-of-plane free tip displacements  $w_f$  of device 3 for different actuations. The yellow, green, red, cyan blue colored lines are the experimental data under triangle wave excitation for applied electric field of 0.5, 0.4, 0.3, 0.2, 0.1 V/ $\mu$ m, and the symbols are averages over 10 cycles. Similarly, Fig. 4.8 shows the experimen-



**Figure 4.7.** Applied electric field  $\phi$  versus free tip out of plane displacement  $w_f$  for Device 3: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle - right flange).

tal and analytical in-plane free tip displacement  $v_f$  versus applied electric field  $\phi$ . The data shows that the analytical predictions closely match the displacement magnitude and trend for the T-beam actuator. The experimental T-beams are not rigidly clamped at the base because the FR4 circuit board is thinner and softer than the T-beam. The electrodes extend all the way to the end of the beam. Sixty percent of the "clamped" region is included in the beam length to model this effect. The experimental displacements are proportional to the applied field. Web and both flange actuation produce similar displacements in opposite directions. Single flange actuation produces less out of plane displacement and, as they should, the left and right flange actuation cases produce similar displacements.



**Figure 4.8.** Applied electric field,  $\phi$  versus in-plane tip displacement,  $v_f$  for Device 3: theoretical (dashdot - Right flange (top), left flange (bottom)) and experimental (plus - left flange, circle - right flange).

The compliance of the FR4 circuit board also affects the blocking force measurements. As as result, perfect clamped boundary conditions could not be realized. Accordingly, the force  $F_3$  is calculated (from Eq.(4.9)) as

$$F_{3} = -\frac{3a_{4}VA_{p}}{2L} - \frac{3\left(2a_{2}I_{p3} + 2a_{3}A_{p} + E_{p}I_{b3}\right)w_{\exp}}{L^{3}},$$
(4.18)

and is shown for device 3 in Fig. 4.9 for web and flange actuations, where,  $w_{exp}$  is the measured displacement of T-beam with tip force. The analytical model predicts the trend accurately but slightly overpredicts the magnitude. The results are linear with applied field and the web and flange actuation produce similar blocking forces at similar field.



**Figure 4.9.** Applied electric field  $\phi$  versus tip force,  $F_3$  for Device 3: Theoretical (solid - web actuation, dashed - flange actuation) and experimental (star - web actuation, diamond - flange actuation).

It should be noted, however, that flange actuation uses less voltage because the flange is thinner than the web. For further analysis, the force measurements are corrected with the measured displacement using Eqns. (4.9) and (4.13) to obtain blocking force as

$$(F_{3b})_{\exp} = (F_3)_{\exp} + \frac{3\left(2a_2I_{p3} + 2a_3A_p + E_pI_{b3}\right)w_{\exp}}{L^3},$$

$$(F^*_{3b})_{\exp} = (F^*_3)_{\exp} - w^*_{\exp},$$
(4.19)

Figure 4.10 shows the nondimensional analytical and experimental displacements  $v_f^*$ ,  $w_f^*$  versus nondimensional voltage  $V_2^*$  and  $V_3^*$ , for Devices 1 - 6. The nondimensional alization allows the in-plane and out-of-plane displacement results for all the devices



**Figure 4.10.** Non-dimensional voltage,  $V_2^*$ ,  $V_3^*$ , versus displacement,  $v_f^*$ ,  $w_f^*$ , for Devices 1 - 6: Theoretical (solid) and experimental (star - web actuation, diamond - flange actuation, square or plus - left flange, triangle or circle - right flange actuation).

in all actuation modes to be plotted against the one theoretical line. Different symbols denote different types of actuation and each color represents a different device. From the plot, it can seen, that the analytical model in general closely predicts the trend and magnitude of all the devices. A linear fit to the data has a slope of 43.3° within 3.8% of the analytical slope of 45°. The 95% confidence interval has a lower limit of 42.5 and a upper limit of 44.1. Device-1 (blue) has inferior flange electrodes that produce poor performance in flange actuation. Device 4 (magenta) in web actuation, however, produced higher displacements than predicted by theory.

Figure 1.10 shows the dimensionless blocking force  $F_{3b}^*$  for Devices 1 - 6 versus



**Figure 4.11.** Non-dimensional blocking force  $F_{3b}^*$  versus nondimensional voltage  $V_3^*$  for Devices 1 to 6: Theoretical (solid) and experimental (star - web actuation, diamond - flange actuation).

dimensionless voltage  $V_3^*$ . The best fit line for the experimental data has a slope of 41.2°, within 8% of the theoretical slope of 45°. The 95% confidence interval of slope has a lower limit of 40.5 and a upper limit of 41.9. Again, the flange actuation cases slightly underperform web actuation, probably due to incomplete coverage of the flanges by the deposited electrodes.

### 4.7 Optimization of the T-beam Cross Section

In this section, we optimize T-beam actuators for maximum tip displacement, blocking force, and mechanical energy by varying the cross section geometry. To generalize the

optimization results, we define six, independent, non-dimensional parameters,

$$b^{*} = \frac{b}{s}, t^{*} = \frac{t}{h}, s^{*} = \frac{s}{h}, L^{*} = \frac{L}{h},$$

$$M^{*} = \frac{Ed_{31}^{2}}{\varepsilon_{33}}, \text{ and } \phi^{*} = d_{31}\phi.$$
(4.20)

The first four parameters are geometry dependent. The non-dimensional parameters  $b^*$  and  $t^*$  are the percentage of web width and flange thickness with respect to total width, s, and total height, h, of the actuator cross section. These two parameters are inversely proportional to the material removed during the fabrication process.  $s^*$  is the aspect ratio of the enclosure from which T-beam is fabricated and  $L^*$  is the slenderness of the T-beam.  $M^*$  is a non-dimensional material parameter that depends on mechanical, electrical, and electromechanical couping coefficients. For a given material,  $M^*$  is constant.  $\phi^*$  is the nondimensional electric field, where  $\phi = \frac{V}{t}$  for flange actuation and  $\phi = \frac{V}{h}$  for web actuation. The free tip displacement,  $w_f$  and the blocking force  $F_{3b}$  are normalized as

$$w_f^{**} = \frac{w_f}{L}, F_{3b}^{**} = \frac{F_{3b}}{EL^2}.$$
 (4.21)

Using Eqns. (4.21), (4.20), (4.10) and (4.11) we can obtain the nondimensional tip displacements,  $w_{f_{flange}}^{**}$  and  $w_{f_{web}}^{**}$ , and blocking forces  $F_{b3_{flange}}^{**}$  and  $F_{b3_{web}}^{**}$  for flange and

web actuations, respectively, in terms of the non-dimensional parameters

$$w_{f_{flange}}^{**} = \frac{3L^* \phi^* b^* t^* (1-b^*)(1-t^*)}{\left((1-b^*)^2 (1+M^*) t^{*4} + b^* t^{*3} (4+M^*) (1-b^*)\right)}, \\ \left((1-b^*)^2 (1+M^*) t^{*4} + b^* t^{*3} (4+M^*) (1-b^*)\right) \\ -6b^* t^{*2} (1-b^*) + 4b^* t^* (1-b^*) + b^{*2}\right), \\ F_{3b_{flange}}^{**} = \frac{3s^* \phi^* b^* t^* (1-b^*) (1-t^*)}{4L^{*3} (b^* + t^* - b^* t^*)}, \\ w_{f_{web}}^{**} = \frac{3L^* \phi^* b^* t^* (1-b^*) (1-t^*)}{\left((1-t^*) b^{*2} \left(t^{*3} - 3t^{*2} + 3t^* - 1 - M^*\right)\right) \\ +2b^* t^* \left(t^{*3} - 2t^{*2} + 3t^* - 2 - M^*/2\right) - t^{*4}\right), \\ F_{3b_{web}}^{**} = -\frac{3s^* \phi^* b^* t^* (1-b^*) (1-t^*)}{4L^{*3} (b^* + t^* - b^* t^*)}, \\ \end{cases}$$
(4.22)

#### 4.7.1 Displacement Optimization

Equation (4.22) shows that the displacements  $w_{f_{flange}}^{**}$  and  $w_{f_{web}}^{**}$  are proportional to nondimensional electric field  $\phi^*$  and slenderness  $L^*$ . For commercially available PZT materials (e.g. PZT-4 and PZT-5H),  $M^*$  ranges from 0.1 to 0.2 and has very little influence on tip displacement. The Equation (4.22) is independent of aspect ratio  $s^*$ , so the shape of the bounding rectangle does not influence the displacement. The optimal design of the actuator depends on only  $b^*$  and  $t^*$ . new non-dimensional displacement



**Figure 4.12.** Contour plot of nondimensional displacement  $(K_w)_{flange}$  versus  $b^*$  and  $t^*$  for PZT-4 material properties (Tab. 4.4)

parameter  $K_w$  for flange and web actuations as a function of  $b^*$ ,  $t^*$ , and  $M^*$  as

$$(K_w)_{flange} = \frac{b^*t^*(1-b^*)(1-t^*)}{\left((1-b^*)^2(1+M^*)t^{*4}+b^*t^{*3}(4+M^*)(1-b^*)\right)},$$

$$(K_w)_{web} = \frac{b^*t^*(1-b^*)+4b^*t^*(1-b^*)+b^{*2}}{\left((1-t^*)b^{*2}\left(t^{*3}-3t^{*2}+3t^*-1-M^*\right)\right)},$$

$$(4.23)$$

$$(4.24)$$

Figure (4.12) is a contour plot of

$$(K_w)_{flange} = \frac{w_{f_{flange}}^{**}}{3L^*\phi^*},$$
 (4.24)

versus  $b^*$  and  $t^*$  for the PZT-4 material properties shown in Tab. 4.4. The inset drawings show the cross-section of the T-beam for extreme of  $b^*$  and  $t^*$ . The contours show that the maximum displacement can be obtained when both  $b^*$  and  $t^*$  tend towards zero, so the configurations with very thin webs and flanges produce maximum displacements. A similar conclusion can be obtained for web actuation. There exists an optimal  $t^*$  for a given  $b^*$  for web and flange actuations,

$$t_{web}^{*} = \frac{b^{*} - \sqrt{b^{*}}}{b^{*} - 1},$$

$$t_{flange}^{*} = \text{Rootof} \begin{pmatrix} 2(-1 + b^{*})^{2}(1 + M^{*})Z^{5} + \begin{pmatrix} (-7 - 4M^{*})b^{*2} - 3M^{*} \\ + (7M^{*} + 10)b^{*} - 3 \end{pmatrix} Z^{4} \\ + 2b^{*}(M^{*} + 4)(b^{*} - 1)Z^{3} + 2(b^{*} - b^{*2})Z^{2} - 2b^{*2}Z + b^{*2} \end{pmatrix},$$
(4.25)

respectively.

Figure 4.13 shows the nondimensionalized displacement versus  $t^*$  for  $b^* = 0.381$  for web (top curve) and flange (bottom curve) actuations. Devices 1 - 6 were designed to span this curve and, as theory predicted, Device 3 (black symbols) is optimal for both flange and web actuation.



**Figure 4.13.** Non-dimensional displacement  $K_w$  versus  $t^*$  for  $b^*=0.381$  with PZT-4 material properties for web (theoretical - solid, experimental - star) and flange (theoretical - dashed, experimental - diamond) actuation.

#### 4.7.2 Blocking Force Optimization

From Eq. (4.22), nondimensional blocking force  $F_{b3}^{**}$  is independent of the material parameter  $M^*$ , is directly proportional to aspect ratio  $s^*$  and field  $\phi^*$ , and inversely proportional to  $L^{*3}$ . Equation (4.22) shows that T-beams produce equal and opposite blocking forces for web and flange actuations. Hence, there exists a single optimal configuration that maximizes blocking force for both web and flange actuations. As the optimal configuration is dependent only on  $b^*$  and  $t^*$ , we define nondimensional blocking force  $K_F$  as

$$K_F = F_{b3}^{**} \frac{4L^{*3}}{3s^* \phi^*},\tag{4.26}$$



**Figure 4.14.** Non-dimensional blocking force  $K_F$  versus b<sup>\*</sup> and t<sup>\*</sup>.

Figure 4.14 shows the contour plot of nondimensional blocking force  $K_F$  versus  $b^*$  and  $t^*$ . The plot shows that there is an optimal solution that maximizes blocking force. The optimal solution is

$$\frac{\partial \left(K_F\right)}{\partial b^*} = 0, \frac{\partial \left(K_F\right)}{\partial t^*} = 0, \tag{4.27}$$

or

$$b^* = t^* = \text{Rootof}(Z^2 - 3Z + 1) \approx 0.381.$$
 (4.28)

T-beams with web widths and flange thicknesses that are 38% of total width and height, respectively, produce maximum blocking force, independent of material properties, field, or slenderness of the actuator and type (web or flange) of actuation.

Figure 4.15 plots the nondimensional blocking force  $K_F$  for web (top) and flange



**Figure 4.15.** Non-dimensional blocking force  $K_F$  versus  $t^*$  for  $b^*=0.381$  for web (theoretical - solid and experimental - star) and flange (theoretical - dashed and experimental - diamond) actuation.

(bottom) actuation. The plot shows that the optimally designed actuator (Device 3 - black) outperforms the other four actuators.

### 4.7.3 Energy Optimization

Mechanical energy stored in the actuator is defined as  $E_M = \frac{1}{2} w_f F_{3b}$ . The nondimensional

mechanical energy

$$(K_E)_{web} = \frac{1}{2} (K_w)_{web} K_F,$$

$$(K_E)_{flange} = \frac{1}{2} (K_w)_{flange} K_F.$$
(4.29)

Figure 4.16 shows the contour plot of  $(K_E)_{flange}$  for flange actuation with PZT-4



**Figure 4.16.** Non-dimensional energy parameter  $K_E$  versus b<sup>\*</sup>, t<sup>\*</sup>

material properties. The plot shows there exists an optimal configuration for a given material. Web actuation shows similar trend. The optimal solution are obtained by the gradient method as

$$b_{web}^{*} = \frac{1}{M^{*}} \begin{pmatrix} 24 \left( \text{Rootof} \left( 12Z^{3} - (28 + 2M^{*})Z^{2} + (20 + 4M^{*})Z - M^{*} - 4 \right) \right)^{2} \\ -20 \text{Rootof} \left( 12Z^{3} - (28 + 2M^{*})Z^{2} + (20 + 4M^{*})Z - M^{*} - 4 \right) \\ -4 \text{Rootof} \left( 12Z^{3} - (28 + 2M^{*})Z^{2} + (20 + 4M^{*})Z - M^{*} - 4 \right) M^{*} \\ +M^{*} + 4 \end{pmatrix},$$
  
$$t_{web}^{*} = \text{Rootof} \left( 12Z^{3} - (28 + 2M^{*})Z^{2} + (20 + 4M^{*})Z - M^{*} - 4 \right), \qquad (4.30)$$

for web actuation. Solving the roots numerically for both web and flange actuations



**Figure 4.17.** Non-dimensional mechanical energy  $K_E$  versus t<sup>\*</sup> for  $b^*=0.381$  (theoretical - black solid (web actuation) and black dashed (flange actuation), Experimental - star (web actuation) and diamond (flange actuation)) and  $b^*=0.25$  (cyan)

gives  $b^* \approx 0.25$  and  $t^* \approx 0.33$  for the piezoelectric materials ( $M^* = 0.1 - 0.2$ ) studied. Figure 4.17 non-dimensional energy  $K_E$  for both web (top) and flange (bottom) actuations with  $b^* = 0.381$  and the optimal  $b^* = 0.25$ . The plot clearly shows that the device with optimal design  $b^* = 0.25$  exceeds the energy performance of the other actuators.

### 4.8 Comparison with Unimorph Actuator

To understand the performance of T-beam actuators compared to state-of-the-art piezoelectric actuators, we compare the T-beam actuators with unimorph actuators. The free tip displacement,  $w_{fU}$  and blocking force  $F_{bU}$  of unimorph actuators[79, 32] are given by

$$w_{fU} = \frac{6\varepsilon_{33}e_{31}L^{2}\phi}{h\left(8E\varepsilon_{33} + e_{31}^{2}\right)},$$

$$F_{bU} = \frac{3e_{31}h^{2}s\phi}{16L},$$
(4.31)

where E is the Young's modulus, h is the total thickness of the passive and active layers, and s and L are the total width and cantilevered length of the actuator.

Using PZT-4 material properties, the displacement per unit cross-section area  $(w_{fA})_U$ of the unimorph

$$(w_{fA})_U = 9 \times 10^{-11} \frac{L^2 \phi}{h^2 s}.$$
 (4.32)

The displacement per unit cross-section area of the T-beam is

$$\left(w_{fA}\right)_{flange} = \frac{w_{f_{flange}}^{**}L}{A} = \left(w_{c}\right)_{flange} \frac{L^{2}\phi}{h^{2}s} \approx \left(w_{fA}\right)_{web},\tag{4.33}$$

for flange and web actuations, respectively, where

$$(w_c)_{flange} = \frac{-0.366E - 9t^*b^*(t^* - 1)(b^* - 1)}{\left(\begin{array}{c} 1.1t^{*4} - 2.2b^*t^{*4} + 1.1b^{*2}t^{*4} + 4.1b^*t^{*3} + b^{*2} - \\ 4.1b^{*2}t^{*3} + 6t^{*2}b^{*2} - 6t^{*2}b^* - 4t^*b^{*2} + 4t^*b^* \end{array}\right)(t^*b^* - t^* - b^*)}$$

$$(4.34)$$

Figure 4.18 shows the contour plot of the flange  $(w_c)_{flange}$  displacement coefficient versus  $b^*$  and  $t^*$ . The shaded regions show where the T-beam displacement coefficient is greater than unimorph displacement coefficient. As the web and flange become thinner



**Figure 4.18.** Flange displacement coefficient  $(w_c)_{flange}$  versus  $b^*, t^*$ 

we realize higher displacements per unit cross-section area than a unimorph with the same thickness and width. In addition, the voltage required in flange actuation is less than that of a unimorph to produce same field.

The optimal blocking force per unit area of the unimorph is

$$(F_{bA})_U = 1.78 \frac{h\phi}{L},$$
 (4.35)

and the blocking force per unit area of T-beam is

$$F_{b3A} = \frac{F_{b3_{flange}}^{**} EL^2}{A} = F_c \frac{h\phi}{L},$$
(4.36)

where the blocking force coefficient  $F_c$  is

$$F_c = -\frac{7.137b^*t^*(t^*b^* - t^* + 1 - b^*)}{(t^*b^* - t^* - b^*)^2},$$
(4.37)

and is same in magnitude for both flange and web actuations.  $F_c$  is maximum in the limit

$$\lim_{b^*, t^* \to 0} (F_c) = 1.78, \tag{4.38}$$

so a T-beam with thin webs and flanges approaches the blocking force per unit area produced by a unimorph.

Similarly, the maximum mechanical energy per unit area for the T-beam is maximum and approaches unimorph as both  $b^*$  and  $t^*$  approach zero for web and flange actuation.

# Chapter 5\_\_\_\_

# Conclusions

In this research, the design, fabrication, and mechanical model of a novel uniflex microactuator combining the strain amplification mechanisms of a unimorph and flexural motion to produce large displacement and blocking force is presented. Uniflex microactuators can provide displacement performance that exceeds that of similarly sized unimorph actuators if the parameters are properly chosen and as demonstrated by the fabricated uniflex devices in this work. The clearance between the unimorph and flexural motion strain amplification mechanisms work together to produce large displacement and blocking force. In the experimentally fabricated uniflex actuators, weakened joint enabled a much larger response and was able to predict reasonable well the observed displacement and blocking force of the various actuators tested. Displacement-optimized uniflex designs produce larger displacements than unimorph and flextensional actuators but their blocking force is smaller than the unimorph. Blocking force optimized uniflex designs outperform flextensional actuators but can only approach the blocking force performance of unimorph actuators.

Also, a novel piezoelectric T-beam actuator is introduced. Analytical models is developed to predict displacement, blocking force, and mechanical energy of T-beam are validated using six successfully fabricated prototypes. Optimization of T-beam cross-section shows that the geometry with ratio of web width *b* to total width *s*,  $b^*$ , and flange thickness *t* to total height *h*,  $t^*$  approaching zero produces maximum displacement. Also, the tip displacement is independent of bounding box of T-beam. The cross section with  $b^* = t^* = 0.381$  produces maximum blocking force, while,  $b^* = 0.25, t^* = 0.33$  produces maximum mechanical energy. A properly designed T-beam has better free tip displacement per unit cross section area than a unimorph. Also, a flange actuated T-beam requires lower voltage than a unimorph to generate same electric field.

#### 5.1 Future Work

For the uniflex actuator, current a spring is modeled to account for inaccuracies in fabrication at the unimorph and aluminum cal interface. The interface can further be studied using fracture mechanics models and further experimentation. For the T-beam actuator, the current model assumes floating electrodes in the passive region. The performance of T-beam under short circuited boundary conditions in the currently passive regions can be studied further. Also, the current work explores the T-beam under uniform electric field across the thickness which necessitates three different bottom ground electrodes. However, using a continuous bottom electrode would enable greater yield in fabrication. To understand T-beam performance under such conditions, analytical model needs to be developed with two dimensional electric field across the thickness. Also, such a model would help understand the bimorph type actuation of T-beam. (where passive regions are applied electric field in the opposite direction as poling). Further, the models that predict the electromechanical coupling factors and performance with constant tip loads or spring loads would enhance the understanding of the Tbeam actuator. Other cross-sections like I, U, L etc... need to be further explored.



# **Additional Results for Uniflex**

# Actuator

# A.1 Constants for Uniflex Displacement

The constants for uniflex displacement in Eqn. 3.1 are

$$C_{1} = - \begin{pmatrix} \left( \begin{array}{c} 6K_{4}K_{t}L_{l}^{3} - 12K_{4}\left(-K_{2} + K_{t}\delta\right)L_{l}^{2} \\ + \left(6K_{4}K_{t}\delta^{2} - 12K_{2}K_{4}\delta + 12K_{2}K_{t}\right) \\ L_{l} + 12K_{2}^{2} - 12K_{2}K_{t}\delta \end{pmatrix} \\ P_{2} \\ L_{l} + 12K_{2}^{2} - 12K_{2}K_{t}\delta \end{pmatrix} \\ - \left( \begin{array}{c} -K_{t}\left(-K_{3} + K_{2}\right)L_{l}^{2} - \\ 2K_{3}\left(-K_{2} + K_{t}\delta\right)L_{l} + \\ \delta\left(K_{3} + K_{2}\right)\left(-2K_{2} + K_{t}\delta\right) \end{pmatrix} P_{l} \\ + 12P_{2}K_{2}K_{4}\left(-K_{t}L_{l} + K_{t}\delta - K_{2}\right) - \end{pmatrix} \end{pmatrix}$$

$$K_{4} (\delta - L_{I})^{3} (K_{t} \delta - K_{t} L_{I} - 4K_{2}) P_{2} K_{I},$$

$$C_{2} = -K_{4} P_{2} K_{I} (\delta - L_{I})^{3} (K_{t} \delta - K_{t} L_{I} - 4K_{2}),$$

$$C_{3} = \begin{pmatrix} (24K_{t} L_{1}^{2} K_{2} K_{4} + 24 (K_{t} K_{3} + K_{2} K_{t}) K_{2}) K_{I} \\ +24 (K_{t} K_{3} + K_{2} K_{t}) K_{4} K_{2} \end{pmatrix},$$

$$C_{4} = \begin{pmatrix} \begin{pmatrix} 2 (L_{I} - \delta)^{2} (12K_{2} + (4L_{I} - 4\delta) K_{t}) K_{3} + \\ 8 (3K_{2} \delta^{2} + (-\delta^{3} + L_{I}^{3}) K_{t}) K_{2} \\ +24 (K_{2} + K_{t} (L_{I} - \delta)) K_{3} K_{2} \end{pmatrix} K_{4} \end{pmatrix} K_{4} K_{I},$$

$$C_{5} = 2 (L_{I} - \delta)^{3} (4K_{2} + K_{t} (L_{I} - \delta)) K_{3} K_{4} K_{I},$$

$$K_{1} = E_{a} A_{a}, K_{2} = E_{a} I_{a}, P_{1} = a_{8} A_{p}, P_{2} = a_{4} A_{p},$$

$$K_{3} = E_{b} I_{be} + 2a_{2} I_{pe} + 2a_{3} A_{p}, K_{4} = E_{b} A_{b} + E_{p} A_{p}.$$

# A.2 Constants for Uniflex Blocking Force

The constants for uniflex blocking force in Eqn. 3.2 are

$$B_{1} = -3K_{2}^{2}K_{I}K_{t}(K_{4}+K_{I})K_{3}^{2}$$
  
-  $(6K_{2}^{3}K_{I}K_{t}(K_{4}+K_{I})+3K_{2}^{2}K_{I}^{2}K_{t}K_{4}L_{I}^{2})K_{3}$   
+  $(-3K_{t}K_{2}^{2}(K_{4}+K_{I})-3K_{I}K_{2}K_{t}K_{4}L_{I}^{2})K_{2}^{2}K_{I},$ 

$$B_{2} = \begin{pmatrix} 12 (-K_{2} + K_{t} (\delta - L_{I})) K_{2}^{3} K_{I} (K_{4} + K_{I}) + 2K_{2}^{2} K_{I}^{2} \\ K_{4} \begin{pmatrix} (3 \delta L_{I} - 3 \delta^{2} - 6L_{I}^{2}) K_{2} + (\delta - L_{I}) \\ (11/2L_{I}^{2} - 1/2 \delta L_{I} + \delta^{2}) K_{t} \end{pmatrix} \end{pmatrix} K_{3} \\ + \begin{pmatrix} 12 (-K_{2} + K_{t} (\delta - L_{I})) K_{2}^{2} K_{I} (K_{4} + K_{I}) + \\ K_{2} K_{I}^{2} (-3K_{2} + K_{t} (\delta - L_{I})) (\delta - L_{I})^{2} K_{4} \end{pmatrix} K_{3}^{2} \\ + K_{I}^{2} K_{4} (-3K_{2} \delta^{2} + (\delta^{3} - L_{I}^{3}) K_{t}) K_{2}^{3}, \end{cases}$$

$$B_{3} = -K_{I}^{2} (\delta - L_{I})^{3} K_{4} (-4K_{2} + K_{t} (\delta - L_{I})) K_{2}K_{3} (K_{2} + K_{3}),$$

$$B_{4} = \begin{pmatrix} 36K_{t}K_{2}^{4} (K_{4} + K_{I}) (\delta - L_{I}) \\ +36K_{2}^{3}L_{I}^{2}K_{I}K_{t}K_{4} (\delta - L_{I}) \end{pmatrix} K_{3}$$

$$+36K_{t}K_{2}^{3} (K_{4} + K_{I}) (\delta - L_{I}) K_{3}^{2},$$

$$B_{5} = \begin{pmatrix} -36 (-K_{2} + K_{t} (\delta - L_{I})) K_{2}^{3} (K_{4} + K_{I}) (\delta - L_{I}) \\ -12 (-3K_{2} + K_{t} (\delta - L_{I})) K_{I} (\delta - L_{I})^{3} K_{4} K_{2}^{2} \end{pmatrix} K_{3}^{2}$$

$$-12K_{I} (\delta - L_{I}) K_{4}K_{2}^{3} (-3K_{2} \delta^{2} + (\delta^{3} - L_{I}^{3}) K_{t}) K_{3},$$

$$B_{6} = 3K_{1}K_{2}^{2}K_{3}^{2}(\delta - L_{I})^{4}K_{4}(-4K_{2} + K_{t}(\delta - L_{I})),$$
  

$$B_{7} = 3K_{3}K_{I}K_{2}\left(\begin{pmatrix} 12K_{t}K_{2}^{2}K_{3} + \\ 4(3L_{I}^{2}K_{t}K_{I} + 3K_{2}K_{t})K_{2}^{2} \end{pmatrix}K_{4} + 12K_{I}K_{2}(K_{t}K_{2}K_{3} + K_{2}K_{2}K_{t})\end{pmatrix},$$

$$B_{8} = 3K_{2}K_{3}K_{I} \left( \begin{pmatrix} (12K_{2}+4K_{t}(L_{I}-\delta)) \\ (L_{I}-\delta)^{2}K_{3} \\ +4K_{2}(3K_{2}\delta^{2}+K_{t}(L_{I}^{3}-\delta^{3})) \\ K_{4}+12K_{2}(K_{2}+K_{t}(L_{I}-\delta))K_{3} \\ K_{I}+12K_{2}(K_{2}+K_{t}(L_{I}-\delta))K_{3}K_{4} \end{pmatrix} \right)$$

$$B_{9} = 3\left(K_{t}K_{I}K_{2}(L_{I}-\delta)^{4}+4(L_{I}-\delta)^{3}K_{2}^{2}K_{I}\right)K_{3}^{2}K_{4}K_{I}K_{2}.$$

## A.3 Maximum Displacement Design

Figure A.1 shows the variation of optimal clearance  $L_1$  with actuator length  $L_a$  for aluminum cap thickesses  $t_a = 1 \ \mu$ m and  $t_a = 0.3 \ \mu$ m. For  $t_a = 1 \ \mu$ m, it can be seen that  $L_a/L_1 \approx 300$  for the actuators considered. Also, the thickness ratio  $t_p/t_b \approx 2$  as shown in Fig. A.2. Figure A.3 shows that the optimal thickness ratio  $t_p/t_b$  varies from 2.1 to 1.6 for the actuator length  $L_a = 300 \ \mu$ m.



**Figure A.1.** Clearance  $L_1$  for maximum displacement versus length ( $L_a$ ): uniflex actuator with  $t_a = 1 \ \mu m$  (dashed) and  $t_a = 0.3 \ \mu m$  (dotted), and flextensional actuator with  $t_a = 1 \ \mu m$  (dash-double dotted).



Figure A.2. Ratio  $t_p/t_b$  for maximum displacement versus length  $L_a$ : uniflex actuator with  $t_a = 1 \ \mu m$  (dashed) and  $t_a = 0.3 \ \mu m$  (dotted), and unimorph actuator (dash-dotted).



Figure A.3. Uniflex actuator ratio  $t_p/t_b$  for maximum displacement versus Al thickness  $t_a$  ( $L_a = 300 \ \mu$ m).

## A.4 Maximum Displacement Design with Additional

### **Flextensional Actuator Results**

Figures A.4 and A.5 show the variation of maximum free displacement and corresponding blocking force F with actuator length  $L_a = 200$  to 500  $\mu$ m. The results clearly show that the uniflex produces a higher displacement than that of the unimorph and the flextensional actuators when the clearance is optimal (see Fig. A.6). Also, a thinner aluminum cap produces greater displacements.



**Figure A.4.** Maximum displacement versus length  $L_a$ : uniflex actuator  $w_2(L)$  with  $t_a = 1 \ \mu m$  (dashed) and  $t_a = 0.3 \ \mu m$  (dotted), unimorph actuator  $w_3(0)$  (dash-dotted), and flextensional actuator  $w_2(L)$  with  $t_a = 1 \ \mu m$  (dash-double dotted) and  $t_a = 0.3 \ \mu m$  (double dash-dotted).


**Figure A.5.** Blocking force *F* for maximum displacement configuration versus length  $L_a$ : uniflex actuator with  $t_a = 1 \ \mu m$  (dashed) and  $t_a = 0.3 \ \mu m$  (dotted), unimorph actuator (dash-dotted), and flextensional actuator with  $t_a = 1 \ \mu m$  (dash-double dotted) and  $t_a = 0.3 \ \mu m$  (double dash-dotted).



**Figure A.6.** Clearance  $L_1$  for maximum displacement versus length  $L_a$ : uniflex actuator with  $t_a = 1 \ \mu m$  (dashed) and  $t_a = 0.3 \ \mu m$  (dotted), and flextensional actuator with  $t_a = 1 \ \mu m$  (dashed) double dotted) and  $t_a = 0.3 \ \mu m$  (double dash-dotted).

### A.5 Maximum Blocking Force Design

Figures A.7 and A.8 show the variation of optimal aluminum cap thickness  $t_a$  and thickness ratio  $t_p/t_b$  with actuator length  $L_a$  for clearances  $L_1 = 2.7 \ \mu m$  and  $L_1 = 2.7 \ \mu m$  that produce maximum blocking force. The plot shows that larger clearances and thicker aluminum cap are needed to produce maximum blocking force, whereas, the thickness ratio  $t_p/t_b$  remains almost constant ( $\approx 1.65$ ) for the clearances considered. Fig. A.9 shows that the thickness ratio does not change with clearance as well.



**Figure A.7.** Al thickness  $t_a$  for maximum blocking force versus length  $L_a$ : uniflex actuator with clearance  $L_1 = 2.7 \ \mu m$  (dashed) and  $L_1 = 40 \ \mu m$  (dotted), and flextensional actuator with  $L_1 = 2.7 \ \mu m$  (dash-double dotted).



**Figure A.8.** Ratio  $t_p/t_b$  for maximum blocking force versus length  $L_a$ : uniflex actuator with clearance  $L_1 = 2.7 \ \mu m$  (dashed) and  $L_1 = 40 \ \mu m$  (dotted), and unimorph actuator (dash-dotted).



Figure A.9. Uniflex actuator ratio  $t_p/t_b$  for maximum blocking force versus clearance  $L_1$  for  $L_a = 300 \ \mu$ m.

# A.6 Maximum Blocking Force Design with Additional Flextensional Actuator Results

Figures A.10 and A.11 show the variation of maximum blocking force F and corresponding displacement with actuator length  $L_a$ . Unimorph actuator produces highest blocking force followed by uniflex and flextensional actuators. Higher clearances produce larger blocking forces in uniflex actuator. Figure A.12 shows that a thicker aluminum cap is needed at larger clearances to produce maximum blocking force.



Figure A.10. Maximum blocking force *F* versus length  $L_a$ : uniflex actuator with clearance  $L_1 = 2.7 \ \mu m$  (dashed) and  $L_1 = 40 \ \mu m$  (dotted), unimorph actuator (dash-dotted), and flextensional actuator with  $L_1 = 2.7 \ \mu m$  (dash-double dotted) and  $L_1 = 40 \ \mu m$  (double dash-dotted).



**Figure A.11.** Displacement for maximum blocking force configuration versus length  $L_a$ : uniflex  $w_2(L)$  with clearance  $L_1 = 2.7 \ \mu$ m (dashed) and  $L_1 = 40 \ \mu$ m (dotted), unimorph actuator  $w_3(0)$  (dash-dotted), and flextensional actuator  $w_2(L)$  with  $L_1 = 2.7 \ \mu$ m (dash-double dotted) and  $L_1 = 40 \ \mu$ m (double dash-dotted).



**Figure A.12.** Al thickness  $t_a$  for maximum blocking force versus length  $L_a$ : uniflex with clearance  $L_1 = 2.7 \ \mu \text{m}$  (dashed) and  $L_1 = 40 \ \mu \text{m}$  (dotted), and flextensional actuator with clearance  $L_1 = 2.7 \ \mu \text{m}$  (dash-double dotted) and  $L_1 = 40 \ \mu \text{m}$  (double dash-dotted).



## **Additional Results for T-beam**

### Actuator

Figures B.1 to B.15 show the out of plane and inplane displacements, and out of plane blocking forces at the tip for the devices 1, 2, 4, 5, and 6 (see Tab. 4.3). Solid lines in yellow, green, red, cyan, and blue represent the experimental data for 500, 400, 300, 200, and 100 V peak actuation voltage of triangle wave, respectively. The symbols (diamond, star, circle, plus, square, and triangle) are the average peak to peak data for 10 cycles.



**Figure B.1.** Applied electric field  $\phi$  versus free tip out of plane displacement  $w_f$  for Device 1: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle - right flange).



**Figure B.2.** Applied electric field,  $\phi$  versus in-plane displacement tip displacement,  $v_f$  for Device 1: theoretical (dashdot - Right flange (top), left flange (bottom)) and experimental (plus - left flange, circle - right flange).



**Figure B.3.** Applied electric field  $\phi$  versus tip force,  $F_3$  for Device 1: Theoretical (solid - web actuation, dashed - flange actuation) and experimental (star - web actuation, diamond - flange actuation).



**Figure B.4.** Applied electric field  $\phi$  versus free tip out of plane displacement  $w_f$  for Device 2: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle - right flange).



**Figure B.5.** Applied electric field,  $\phi$  versus in-plane displacement tip displacement,  $v_f$  for Device 2: theoretical (dashdot - Right flange (top), left flange (bottom)) and experimental (plus - left flange, circle - right flange).



**Figure B.6.** Applied electric field  $\phi$  versus tip force,  $F_3$  for Device 2: Theoretical (solid - web actuation, dashed - flange actuation) and experimental (star - web actuation, diamond - flange actuation).



**Figure B.7.** Applied electric field  $\phi$  versus free tip out of plane displacement  $w_f$  for Device 4: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle - right flange).



**Figure B.8.** Applied electric field,  $\phi$  versus in-plane displacement tip displacement,  $v_f$  for Device 4: theoretical (dashdot - Right flange (top), left flange (bottom)) and experimental (plus - left flange, circle - right flange).



**Figure B.9.** Applied electric field  $\phi$  versus tip force,  $F_3$  for Device 4: Theoretical (solid - web actuation, dashed - flange actuation) and experimental (star - web actuation, diamond - flange actuation).



**Figure B.10.** Applied electric field  $\phi$  versus free tip out of plane displacement  $w_f$  for Device 5: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle - right flange).



**Figure B.11.** Applied electric field,  $\phi$  versus in-plane displacement tip displacement,  $v_f$  for Device 5: theoretical (dashdot - Right flange (top), left flange (bottom)) and experimental (plus - left flange, circle - right flange).



**Figure B.12.** Applied electric field  $\phi$  versus tip force,  $F_3$  for Device 5: Theoretical (solid - web actuation, dashed - flange actuation) and experimental (star - web actuation, diamond - flange actuation).



**Figure B.13.** Applied electric field  $\phi$  versus free tip out of plane displacement  $w_f$  for Device 6: Theoretical (solid - web actuation, dashed - flange actuation, dashdot - right or left flange actuation) and experimental (star - web actuation, diamond - flange actuation, square - left flange, and triangle - right flange).



**Figure B.14.** Applied electric field,  $\phi$  versus in-plane displacement tip displacement,  $v_f$  for Device 6: theoretical (dashdot - Right flange (top), left flange (bottom)) and experimental (plus - left flange, circle - right flange).



**Figure B.15.** Applied electric field  $\phi$  versus tip force,  $F_3$  for Device 6: Theoretical (solid - web actuation, dashed - flange actuation) and experimental (star - web actuation, diamond - flange actuation).

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#### EDUCATION

PhD, Dept. of Mechanical Engineering, The Pennsylvania State University, University Park, PA May 2010

- GPA 3.97/4.00
- PhD minor in Computational Science

Master of Science, Dept. of Mechanical and Nuclear Engineering, The Pennsylvania State University, University Park, PA December, 2008

• GPA 3.97/4.00

Master of Technology, Dept. of Mechanical Engineering, Indian Institute of Technology Madras, India, April 2003 • GPA 9.42/10.00 (Rank 2)

- Bachelor of Technology, Dept. of Mechanical Engineering, Sri Krishnadevaraya University, India, April 2001
- Percent- 85% (Topper Gold medalist)

#### **RESEARCH INTERESTS**

My research interests include Solid mechanics, Micro-Electro-Mechanical Systems (MEMS), Structural Dynamics, Finite Element Analysis, Control Systems, and Bio-mechanics.

#### PUBLICATIONS

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#### WORK EXPERIENCE

- Design Engineer at General Electric Aviation, Bangalore India, 2003 2005
- Summer Intern at General Electric Global Research Center, Niskayuna, NY Summer, 2008 & Summer, 2009
- Graduate research assistant at Mechatronics Research Laboratory, The Pennsylvania State University, 2006 2010
- Graduate teaching assistant at The Pennsylvania State University, 2005 2006

#### AWARDS AND ACHIEVEMENTS

- Obtained Tau Beta Pi, Golden Key membership for academic excellence at The Pennsylvania State University
- Received three management awards and highly coveted "Hats off award" for outstanding performance, stretch and delivering the high quality results meeting the strict business deadlines at *General Electric Aviation*
- Awarded prestigious "DAAD Fellowship" (German Academic Exchange Service) during the master's program
- Awarded the prestigious "Young Engineering Fellowship" by the Indian Institute of Science, Bangalore, during summer 2000
- Member of American Society of Mechanical Engineers (ASME)